– Index –

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SOVIET PHYSICS – SOLID STATE: AUTHOR INDEX

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Abakarov, Dzh. I., and Yu. M. Seiidov. The Theory of the Magnetic Susceptibility of the Polaron. -2019

Abdullaev, G. B., see Akhundov, G. A. -1378

Adirovich, É. I., Electric Fields and Currents in Dielectrics. - 1282

Adirovich, É. I., A New Method of Determining the Effective Cross Sections of Local Centers. -2006

Adirovich, É. I., The Kinetics of Impurity Photoconductivity and the Effective Cross Sections of Local Centers. -2123

Aéro, É. L., and E. V. Kuvashinskii. Fundamental Equations of the Theory of Elastic Media with Rotationally Interacting Particles. -1272

Agaev, Ya., and D. N. Nasledov. Some Electrical Properties of the AlSb-InSb System. -758

Ageev, V. N., L. A. Balabanova, and M. M. Bredov. Investigation of Plasmon Spectra. -2578

Agranovich, V. M., On the Theory of Circular Dichroism in Crystals. -1085

Agranovskaya, A. I., see Krainik, N. N. -63

Agranovskaya, A. I., see Smolenskii, G. A. -2584

Agranovskaya, A. I., see Smolenskii, G. A. -2651

Airapetyants, S. V., and G. I. Shmelev. Method for Growing Uniform Monocrystals of Alloyed Semiconductor Materials, Solid Solutions, and Intermetallic Compounds of a Given Composition Determined by the Composition of the Melt. -689

Aizenberg, N. B., The Passage of Electrons Through a Rectangular Potential Barrier with a Small Cylindrical Inhomogeneity. -1067

Akhiezer, A. I., and V. G. Bar'yakhtar. Theory of Heat Conductivity in Ferrodielectric Materials at Low Temperatures. -2178

Akhundov, G. A., G. B. Abdullaev, and G. D. Guseinov. Certain Properties of Thallium Selenide Monocrystals. -1378

Akimchenko, I. P., and L. S. Milevskii. Diffusion of Antimony in Germanium Alloyed with Aluminum. -1891

Amirkhanova, D. Kh., Thermomagnetic Properties of Gallium Antimonide. -1019

Amirkhanova, D. Kh., and R. I. Bashirov, Effect of a Magnetic Field on the Heat Conduction of Indium Antimonide. -1447

Andreev, A.A., and A. R. Regel'. Electrical Conductivity of Liquid Selenium in Strong Electric Fields. -2467

Andreev, G. A., see Vorob'ev, A. A. -896

Andreev, N. S., V. I. Aver'yanov, and N. A. Voishvillo, Structural Interpretation of the Anomalous Scattering of Visible Light in Sodium Borosilicate Glasses. -916

Andrievskii, A. I., and I. D. Nabutovich, Structural Transformations of Thin Layers of Tungsten. -892

Andrievskii, A. I., A. V. Sandulova, and M. I. Yurkevich. Diffusion of Silver into Cuprous Oxide. -581

Andronik, I. K., and M. V. Kot. Anisotropy of Electrical Properties of Single Crystals of Cadmium Antimonide. -1022

Ansel'm, A. I., and B. M. Askerov. Thermomagnetic Phenomena in Semimetals in a Strong Magnetic Field. -2060

Ansel'm, A. I., and B. M. Askerov. The Chemical Potential and the Criterion for Degeneracy of the Conductivity Electrons in a Strong Magnetic Field. -2512

Ariya, S. M., and G. Groesmann. Magnetic Suceptibility of Solid Solutions of Vanadium Dioxide in Titanium Dioxide. -1166

Ariya, S. M., see Grossmann, G. -2208

Arkad'eva, E.N., L. G. Paritskii, and S. M. Ryvkin. Investigation of the Kinetics of Infrared Impurity Photoconductivity in CdS Induced by Preliminary Illumination. -1051.

Arkad'eva, E. N., and S. M. Ryvkin, Induced Infrared Photosensitivity in Certain Semiconductors. -1704

Arkovenko, G. I., see Vasil'ev, D. M. -507

Artamonov, O. M., and L. P. Strakhov. Appearance of the emf in Lead Sulfide Films on Being Irradiated by Slow Electrons. -715

Askerov, B. M., see Ansel'm, A. I. -2060

Askerov, B. M., see Ansel'm, A. I. -2512

Atsarkin, V. A., and E. Z. Mazel'. Effect of Thermal Treatment of Silicon on Minority Carrier Lifetime. -1874

Avak'yants, G. M., Concerning the Properties of Germanium in a Strong Electric Field. -744

Averkin, A. A., V. M. Sergeeva, and A. I. Shelykh. The Influence of Omnidirectional Pressure upon the Electrical Conductivity and Thermal Electromotive Force of In_2Te_3. -319

Aver'yanov, V. I., see Andreev, N. S. -916

Avetikov, V. G., A. S. Zlatkis, M. D. Mashkovich, and N. Yu. Rozenberg, Investigation of Dielectric Loss and Dielectric Constants of Certain Forms of Ceramics in the Ultrahigh-Frequency Region. -2225

Badenko, L. A., see Konstantinov, B. P. - 2400

Balabanova, L. A., see Ageev, V. N. -2578

Balygin, I. E., Creep of Silver on the Surface of Ceramic Dielectrics. -1558

Banasevich, S. N., B. G. Lur'e, and A. N. Murin, Determination of the Effective Charge of Calcium Ions in NaCl + $CaCl_2$ Solid Solution. -72

Baranov, B. V., and N. A. Goryunova. Preparation of Homogeneous Solid Solutions in the AlSb – InSb System. -262

Baranskii, P. I., The Volume-Gradient Thomson Effect. -413

Baranskii, P. I., Nature of Bulk-Gradient emf Arising in the Presence of Current. -429

Baranskii, P. I., and P. M. Kurilo. Dependence of the Volume Peltier Effect on Resistivity Gradients. -424

Baranskii, P. I., and S. L. Tomkevich. Bridgman Effect in Bismuth Telluride Crystals. -1551

Bar'yakhtar, V. G., see Akhiezer, A. I. -2178

Bashirov, R. I. see Amirkhanova, D. Kh. -1447

Batanov, G. M., Secondary Emission from No. 46 Glass under the Effect of Positive Ions of Some Gases. -1839

Bekker, Ya. M., Effect of Uniaxial, Compressive Mechanical Loading on the Magnetization of Certain Ferrites. -1546

Belova, N. A., A. N. Kovalev, and N. A. Penin. Influence of Current-Carrier Generation in the Barrier Layer on the Form of the Reverse Branch of the Current-Voltage Characteristic of Germanium Diodes. -2360

Belyaev, A. D., V. N. Vasilevskaya, and E. G. Miselyuk. Investigation of the Effect of Certain Factors on Formation of Dislocations During Crystallization and on the Dislocation States in Germanium Monocrystals. -208

Berkovskii, F. M., S. M. Ryvkin, and N. B. Strokan. Forward Current-Voltage Characteristics of a Barrier Layer in a Germanium p-n Junction. -1762

Berlaga, R. Ya., and T. T. Bykova. The Effect of Adsorbed Oxygen on the Photo-emf of Lead Sulfide Layers. -2705

Berman, L. S., and V. K. Subashiev, Investigation of the Barrier Capacitance of Diffused p-n Junctions in Silicon. -1768

Bir, G. L., and G. E. Pikus. Theory of the Deformation Potential for Semiconductors with a Complex Band Structure. -2039

Blistanov, A. A., see Shaskol'skaya, M. P. -2025

Blum, A. I., Observation of Dislocations in Tellurium. -1509

Bogatyrev, A. N., see Fridkin, V. M. -1952

Bogdanov, S. V., and R. Ya. Razbash. The Nature of a High-Temperature Phase Transition in Some $BaTiO_3 - BaSnO_3$ Solid Solutions. -621

Bogomolov, Yu. V., Effective Fields in Crystals. -275

Boiko, I. I., Role of Trapping Centers in the Relaxation of Photoconductivity. -1658

Boiko, I. I., É. I. Rashba, and A. P. Trofimenko, Thermally Stimulated Conductivity in Semiconductors. -99

Boiko, I. I., and É. I. Rashba, The Properties of Semiconductors with Extremal Loops. II. Magnetic Susceptibility in a Field Perpendicular to the Plane of the Loop. -1692

Bokov, V. A., and I. E. Myl'nikova. Ferroelectric Properties of Monocrystals of New Perovskite Compounds. -2428

Bol'shov, V. G., L. V. Vasil'eva, and G. N. Pautova, Emission Properties of Silicon Treated in Cesium Vapors. -1783

Boltaks, B. I., G. S. Kulikov, and R. Sh. Malkovich. The Effect of Gold on the Electrical Properties of Silicon. -167

Boltaks, B. I., G. S. Kulikov, and R. Sh. Malkovich. Electrical Transport of Gold in Silicon. -2134

Boltaks, B. I., and Hsüeh Shih-yin. Diffusion, Solubility and the Effect of Silver Impurities on Electrical Properties of Silicon. -2383

Bonch-Bruevich, V. L., Concerning the Dependence of Phonon Spectrum on the Concentration of Free Charge Carriers. -1678

Bonch-Bruevich, V. L., and Yu. V. Gulyaev. On the Theory of Collision Recombination in Semiconductors. -431

Bonch-Bruevich, V. L., and A. G. Mironov. On the Theory of Electron Plasma in a Magnetic Field. -454

Bonch-Bruevich, V. L., see Landsberg, E. G. -777

Bonderenko, B. V., Temperature Dependence of the Work Function of Semiconductor Thermionic Cathodes. -1916

Borodinets, L. A., see Pilat, I. M. -1381

Borzyak, P. G., and R. D. Fedorovich, Intrinsic Optical Absorption in Amorphous and Crystalline Germanium. -39

Borzyak, P. G., and R. D. Fedorovich. Optical Properties and Photoelectron Emission of Amorphous and Crystalline Germanium Films. -2683

Borzyak, P. G., P. M. Marchuk, and P. G. Sarbei. Current-Voltage Characteristics of Photoelectron Emission from Germanium. -284

Borzyak, P. G., L. S. Miroshnichenko, and O. G. Sarbei. Photoelectron Emission from Germanium and Silicon in the Amorphous and Crystalline States. -290

Brailovskaya, R. V., see Mazurin, O. V. -1341

Brainin, É. I., see Davidenkov, N. N. -1642

Brakhman, É. V., see Fridkin, V. M. -1952

Bredov, M. M., see Ageev, V. N. -2578

Britsyn, K. I., see Vavilov, V. S. -1746

Brodin, M. S., Optical Properties of CdS Monocrystals. -1926

Bronshtein, I. M., and R. B. Segal', Secondary Electron Emission from Thin Metal Films on an Activated Base. -84

Budylin, B. B., see Vorob'ev, A. A. -615

Budylin, B. V., Effect of Radiation on the Mechanical Properties of Ionic Crystals. -2214

Buimistrov, V. M., and V. N. Piskovoi. Investigation of the Accuracy of the Variational Method in the Problem of Impurity Absorption of Light in Silicon. -569

Buishvili, L. L., Concerning the Overhauser Effect in Metals with Paramagnetic Impurities. -2023

Buishvili, L. L., and G. R. Khutsishvili. Forbidden Paramagnetic Resonance. -1524

Bulashevich, T. Yu., see Korovin, L. I. -2489

Burkin, A. L., and I. T. Shefmel'. Cobalt-Manganese Semiconducting Oxide Bolometers. -267

Burlakov, A. V., see Oksman, Ya. A. -1644

Burlakov, A. V., see Oksman, Ya. A. -1700

Burshtein, A. I., Concerning the Regeneration Circuit of Thermoelectric Cooling. -1456

Burshtein, A. I., Concerning Efficiency Cascade Thermogenerators. -2232

Burshtein, A. I., Concerning the Efficiency of Thermobattery Cooling. -2236

Butsko, N. I., Certain Peculiarities of Photoconductivity of Mercuric Sulfide. -585

Bykova, T. T., see Berlaga, R. Ya. -2705

Chanyshev, S. I., and V. É. Zgaevskii. The Temperature Dependence of the Chemical Potential in a Semiconductor. -2193

Chernaya, N. S., see Lyashenko, V. I. -2158

Chevychelov, A. D., see Gubanov, A. I. -1253

Chih-ch'ao, Lien, and D. N. Nasledov. Influence of the Electric Field on the Electrical Conductivity, Hall Coefficient, and Magnetoresistance of n-Type InSb at Low Temperatures. -729

Chikin, A. N., see Kunin, V. Ya. -2101

Chirkin, L. K., see Pasynkov, V. V. -403

Chizhikov, D. M., and V. M. Edel'shtein, The Distribution Coefficient of Tin in Selenium. -790

Chizhikov, D. M., and V. P. Schastlivyi. State Diagram and Magnetic Susceptibility of Calcium-Iron Silicates. -1148

Chudnovskii, A. F., Various Steady-State Methods for Measuring the Thermal Conductivity of Semiconductors. -2610

Chuenkov, V. A., Electrical Conductivity of Valence Semiconductors at Low Temperatures in Strong Electric Fields. -734

Chun-ming, Lin, see Kolomiets, B. T. -154

Davidenkov, N. N., Measurement of Residual Stresses in Electrolytic Deposits. -2595

Davidenkov, N. N., and É. I. Brainin, Nature of Shear Formation on the Yield Surface of Metals. -1642

Davidenkov, N.N., V. A. Likhachev, and G. A. Malygin. Irreversible Thermal Changes of Shape in Cadmium-Lead and Cadmium Zinc Alloys. -2183

Demidenko, Z. A., and K. B. Tolpygo. Injection Phenomenon during Flow of Current Through a Nonhomogeneous Semiconductor. -2452

Devytakova, E. D., A. V. Petrov, I. A. Smirnov, and B. Ya. Moizhes. Fused Quartz as a Model Material in Thermal Conductivity Measurements. -681

Devytakova, E. D., and I. A. Smirnov. Thermal Conductivity of p- and n-Type Germanium with Different Carrier Concentrations in the Temperature Range 80 to 440°K. -527

Devytakova, E. D., and I. A. Smirnov, The Thermal Conductivity and the Dependence of the Lorentz Number in PbSe on Temperature and on the Degree of the Electron-Gas Degeneracy. -1786

Didenko, A. A., Yu. A. Nemilov, and V. I. Fomina. An Investigation of the Conductivity Induced in Thin Zinc Sulfide Layers. -1304

Dubrovskii, G. B., Quantum Efficiency of CdTe p-n Junctions in the Ultraviolet Part of the Spectrum. -536

Dubrovskii, G. B., and V. K. Subashiev. Determination of Recombination Constants from the Spectral Characteristics of p-n Junction Photocells. II. -1418

Dubrovskii, G. B., see Subashiev, V. K. -925

Dubrovskii, G. B., see Subashiev, V. K. -1781

Dudkin, L. D., Crystal-Chemical Characteristics of Semiconducting Compounds of Transition Metals. -371

Dudkin, L. D., and V. I. Vaidanich. The Nature of the Electrical Conductivity of Certain Compounds of Transition Metals with $CuAl_2$-Type Lattices. -377

Dudkin, L. D., and V. I. Vaidanich. Nature of the Chemical Bonds and Electrical Conductivity of Compounds of the Structure Type of FeS_2. -1384

Dunina, A. A., see Shamovskii, L. M. -2252

Dykman, I. M., and P. M. Tomchuk. Effect of Electric Field on the Temperature of Electrons, Electrical Conductivity, and Thermionic Emission of Semiconductors. I. Atomic Semiconductors, Development of Method. -1988

Édel'shtein, V. M., see Chizhikov, D. M. -790

Éliashberg, M. B., see Stekhanov, A. I. -2096

Elistratov, A. M., and P. R. Kamadzhiev. Study of Decomposition of a Supersaturated Solid Solution of Copper in Germanium. -2621

Elistratov, A. M., and R. A. Zvinchuk. The Appearance and Liquidation of Heterogeneous Regions in Monocrystals of Solid Solutions of (K, Na) Cl. -2111

Emel'yanenko, O. V., and F. P. Kesamanly. Concerning a Rapid Method of Precise Measurements of Thermal emf of Semiconductors. -1356

Emel'yanenko, O. V., T. S. Lagunova, and D. N. Nasledov. Scattering of Current Carriers in Gallium Arsenide in the Presence of Strong Degeneracy. -176

Emel'yanenko, O. V., D. N. Nasledov, and R. V. Petrov. The Nernst-Ettingshausen Effect in p-Type Gallium Arsenide. -2188

Érastov, L. N., Inversion of Thermoelectric Power in the Region of Welded Contacts Between Metals. -254

Érastov, L. N., Detection of Formation of Chemical Compounds in Binary Alloys Using the Resistance Welding Method. -256

Eremenko, V. V., Investigation of the Photoconductivity Response Spectrum of CdSe Monocrystals at 77 and 20°K. -2315

Eremenko, V. V., Investigation of the Photoconductivity Response Spectrum of Mixed $CdS_x \cdot CdSe_{1-x}$ Monocrystals at 77 and 20°K. -2320

Eremenko, V. V., and V. S. Medvedev. Dependence of the Photoconductivity and the Intensity of Luminescence of Anthracene Crystals on the Excitation Wavelength. -1426

Ermakova, L. A., see Koptsik, V. A. -643

Evdokimova, V. V., and L. F. Vereshchagin. Determination of Interatomic Distances of Solids Under Pressure. I. Compressibility of Barium and Strontium. -1539

Evseev, Z. Ya., Band Structure of the Polaron Energy Spectrum. -1107

Fakidov, I. G., see Samokhvalov, A. A. -386

Farbshtein, I. I., see Parfen'ev, R. V. -2599

Fedorovich, R. D., see Borzyak, P. G. -39

Fedorovich, R. D., see Borzyak, P. G. -2683

Fedorus, G. A., see Sal'kov, E. A. -1429

Fedorus, G. A., see Trofimenko, A. P. -1033

Fedoseeva, O. P., see Gliberman, A. Ya. -2306

Feltin'sh, I. A., see Nasledov, D. N. -755

Fiks, V. B., and G. E. Pikus. Electrokinetic Effects in Liquid Semiconductors. -58

Fiks, V. B., and G. E. Pikus. On the Analysis of Microimpurities by the Magnetic Resonance Mass Spectrometer. -660

Fiks, V. B., see Pikus, G. E. -2774

Fistul', V. I., and O. B. Orzhevskii. The Conductivity of p-n Junctions in the Reverse Direction. -1976

Fogel'son, R. L., The Equation of Diffusion. -824

Fomin, N. V., Absorption of Infrared Radiation by Semiconductors in an Electric Field. -566

Fomina, V. I., see Didenko, A. A. -1304

Fridkin, V. M., A. N. Bogatyrev, and É. V. Brakhman. A Parallel Study of Depolarization and Electroluminescence of ZnS Photoelectrets. -1952

Fridkin, V. M., see Golovin, B. M. -911

Fridrikhov, S. A., Secondary Electron Emission and Elastic Reflection of Slow Electrons from NaCl Single Crystals. -157

Fridrikhov, S. A., see Kapitza, M. L. -482

Galavanov, V.V., The Voltage Sensitivity of Hall-Emf Probes. -55

Galkin, G. N., Volume Recombination in p-Type Silicon Subjected to Heat-Treatment at High Temperatures. -5

Galkin, G. N., N. S. Rytova, and V. S. Vavilov. Volume Recombination of Current Carriers in n-Type Silicon Containing Radiation-Induced Structural Defects. -1819

Galushka, A. P., see Konozenko, I. D. -1436

Ganichev, D. A., see Shul'man, A. R. -495

Garber, R. I., I. A. Gindin, and L. M. Polyakov. The Dispersion and Reestablishment of Contacts Between Microblocks During Plastic Deformation. -984

Garber, R. I., I. A. Gindin, B. G. Lazarev, and Ya. D. Starodubov. Low-Temperature Recrystallization of Copper. -991

Garber, R. I., and L. M. Polyakov, Investigations of Ultramicroscopic Inhomogeneities of the Plastic Deformation of Rock Salt. II. -884

Garber, R. I., S. Ya. Zalivadnyi, and V. M. Mikhailovskii. The Change in the Microstructure of Uranium on Cyclic Heat Treatment. -950

Gashimzade, F. M., Investigation of the Symmetry Properties of Energy Bands of Crystals of the SnSe and Sb_2S_3 Type. -1856

Gashimzade, F. M., Symmetry of Energy Bands in TlSe-Type Crystals. -2700

Gashimzade, F. M., see Gubanov, A. I. -236

Gavrishchak, I. V., see Shneider, A. D., -1865

Gel', E. P., see Shul'man, A. R. -489

Geller, I. Kh., and P. V. Sharavskii. About the Electric Parameters of Some Types of Selenium Rectifiers. -1310

Genkina, S. M., and K. B. Tolpygo. The Effect of the Discrete Crystal Structure on the Energy, the Effective Mass, and the Dispersion Law of the Polaron. -2138

Gerasimov, A. B., see Lyashenko, V. I. -2158

Gindin, I. A., and Ya. D. Starodubov. Slip at the Boundaries of Twins During Forward and Reverse Twinning of Iron. -968

Gindin, I. A., see Garber, R. I. -984

Gindin, I. A., see Garber, R. I. -991

Gintsburg, M. A., The Theory of Spin Waves. -833

Ginzburg, V. L., Some Remarks on Phase Transitions of the Second Kind and the Microscopic Theory of Ferroelectric Materials. -1824

Giterman, M. Sh., and Yu. P. Irkhin, Theory of Electrical Conductivity of Antiferromagnetic Polar Crystals. -134

Giterman, M. Sh., see Vonsovskii, S. V. -1622

Gitsu, D. V., and G. A. Ivanov, Electrical Properties of Single Crystals of Bismuth and Its Alloys. I. Galvanomagnetic Properties of Pure Bismuth. -1323

Gitsu, D. V., and G. A. Ivanov. Electrical Properties of Single Crystals of Bismuth and Its Alloys. II. Galvanomagnetic Properties of Bismuth-Tellurium (Solid Solutions). -1330

Glauberman, A. E., V. V. Vladimirov, and I. V. Stasyuk, Theory of Elementary Perturbations in Atomic Crystals. -123

Glazunov, P. Ya., see Vavilov, V. S. -1301

Gliberman, A. Ya., and O. P. Fedoseeva. The Effect of Crystallographic Orientation of Silicon on the Properties of Phototransducers. -2306

Gliberman, A. Ya., A. K. Zaitseva, and A. P. Landsman. Photoelectric Converter Made of Polycrystalline Silicon. -1583

Godik, É. É., and B. F. Ormont. The Applicability of the Diffuse Reflection Spectrum Method for Determining the Forbidden Zone Width ΔE_{phot} in Powder Specimens. -2680

Gofman, I. L., O. D. Protopopov, and G. N. Shuppe. Investigation of Electrostatic Emission of Electrons From a Tungsten Emitter in Pulse Operation. -1203

Golikova, O. A., see Vinogradova, M. N. -1298

Golovin, B. M., N. T. Kashukeev, I. N. Orlov, and V. M. Fridkin, The Photoelectretic State in ZnS and Two New Electrophotographic Processes. -911

Golubeva, I. A., see Voitsekhovskaya, I. A. -2260

Gomoyunova, M. B., and G. A. Ivanov. The Effect of Electrons Inelastically Reflected from Various Types of Support on Secondary Electron Emission from Thin NaCl Films. -294

Gorban', I. S., and V.B. Timofeev. Absorption of Light by Cuprous Oxide Layers. -1005

Gorban', I. S., and V. B. Timofeev. Polarization in the Absorption Spectrum of Cubic Cuprous Oxide. -1863

Gordeev, G. V., the Problem of Internal Breakdown in Nonpolar Semiconductors. -571

Goryunova, N. A., B. T. Kolomiets, and V. P. Shilo. Vitreous Semiconductors 9. Vitrification in Complex Chalcogenides Based on Arsenic Sulfide and Selenide. -258

Goryunova, N. A., and V. D. Prochukhan, Solid Solutions in Quaternary Systems formed from InAs and InSb. -161

Goryunova, N. A., see Baranov, B. V. -262

Gosteva, M. I., see Shamovskii, L. M. -2252

Grechanik, L. A., N. V. Petrovykh, and V. G. Karpechenko. Preparation and Properties of Glassy-Oxide Semiconductors of the $VO_{2.5} - PO_{2.5} - RO_X$ Type. -1908

Gribnikov, Z. S., Avalanche Breakdown in a Diode with a Limited Space-Charge Layer. -782

Grinberg, A. A., Theory of the Anisotropic Photomagnetic Effect in Germanium. -142

Grinberg, A. A., The Photomagnetic Effect in Isotropic Semiconductors and Its Use in Measuring the Lifetime of Minority Current Carriers. -766

Grinberg, A. A., Theory of the Photomagnetic Effect in Cubic Anisotropic Crystals. -1235

Grinberg, A. A., and S. R. Novikov. Utilization of the Longitudinal and Transverse Magnetoconcentration Effects to Determine the Magnetoconductivity Coefficients in Anisotropic Crystals with Cubic Symmetry. -2415

Grinberg, A. A., L. G. Paritzkii, and S. M. Ryvkin. The Effect of Trapping Levels in Semiconductors on Steady State Photoconductivity and Nonequilibrium Carrier Lifetime. -1403

Grinberg, A. A., and N. B. Strokan. Effect of the Surface Recombination Rate and the Absorption Coefficient on Transient Characteristics of Photodiodes. -1394

Grinberg, A. A., see Ryvkin, S. M. -541

Gross, E. F., and A. A. Kaplyanskii. Quadrupole Optical Excitation of the Basic State of Excitons on a Cuprous Oxide Crystal. -353

Gross, E. F. and A. A. Kaplyanskii. Splitting of the Fundamental Absorption Edge of Cu_2O Produced upon Elimination of Band Degeneracy by an Oriented Deformation of the Crystals. -1518

Gross, E. F., and A. A. Kaplyanskii. Investigation of the Influence of Oriented Deformations upon the Spectrum of the Basic Absorption Edge of Single Cu_2O Crystals. -2637

Gross, E. F., B. S. Razbirin, and V. I. Safarov. An Investigation of the Long-Wavelength Fundamental Absorption Edge of CdS and ZnSe Polycrystalline Layers at Low Temperatures. -2617

Gross, E. F., and V. V. Sobolev. Fine Structure of the Fundamental Absorption Edge in Single Crystals of Cadmium Selenide. -379

Grossmann, G., and S. M. Ariya. Magnetic Susceptibility of the Solid Solution of the Ferrous Oxide in the Magnesium Oxide. -2208

Grossmann, G., see Ariya, S. M. -1166

Gubanov, A. I., Quasi-Classical Theory of Amorphous Ferromagnetics. -468

Gubanov, A. I., On the Theory of Amorphous Conductors. -605

Gubanov, A. I., and A. D. Chevychelov, Calculation of the Energy Spectrum for Strongly Anisotropic Crystals. -1253

Gubanov, A. I., and F. M. Gashimzade. Structure of the Energy Bands in Semiconductors of the $CdIn_2Se_4$ Type. -236

Gubanov, A. I., and O. E. Pushkarev. Valence Bond Wave Functions in Certain Crystals. -1607

Gubkin, A. N., The Ferroelectric Properties of Strontium-Bismuth Titanate. -2782

Gulyaev, Yu. V., see Bonch-Bruevich, V. L. -431

Gurevich, L. É., and Z. I. Uritskii. Theory of Infrared Absorption in Crystals. -1123

Gurevich, L. É., and V. I. Vladimirov. Kinetic Theory of Strength. -1613

Gurevich, V. M., and I. S. Rez. Transitional dc Conduction Processes in Ceramic Barium Titanate. -624

Gurevich, V. M., I.S. Zheludev, and I. S. Rez. The Nature of the Transitional Conduction Processes in Piezoelectric Materials. -638

Guseinov, G. D., see Akhundov, G. A. -1378

Hsueh Shih-yin, see Boltaks, B. I. -2383

Iglitsyn, M. I., and L. I. Kolesnik. Effect of Linear Dislocations on Carrier Recombination in Hole Conducting Germanium. -1400

Iglitsyn, M. I., and Yu. A. Kontsevoi. Determination of the Physical Parameters of Recombination Centers Created by Copper in Germanium. -1039

Ioffe, A. F., B. Ya. Moizhes, and L. S. Stil'bans. On Power Applications of Thermoelectric Elements. -2524

Ioffe, A. F., see Ioffe, A. V. -719

Ioffe, A. V., and A. F. Ioffe, Thermal Conductivity of Semiconductor Solid Solutions. -719

Ioffe, V. A., and G. I. Khvostenko. The Electrical Conductivity of Sodium Aluminosilicate Glasses. -475

Ioffe, V. A., I. B. Patrina, and L. S. Poberovskaya. Electrical Properties of Certain Semiconducting Oxide Glasses. -609

Irkhin, Yu. P., see Gitermann, M. Sh. -134

Ishchuk, V. A., see Zingerman, Ya. P. -2030

Iskra, V. D., see Samoilovich, A. G. -2517

Isupov, V. A., see Smolenskii, G. A. -2584

Isupov, V. A., see Smolenskii, G. A. -2651

Ivankina, M.S., see Zavadovskaya, E. K. -617

Ivanov, G. A., see Gitsu, D. V. -1323

Ivanov, G. A., see Gitsu, D. V. -1330

Ivanov, G. A., see Gomoyunova, M. B. -294

Ivanov, I. G., see Pines, B.Ya. -872

Ivanov, Yu. L., see Ryvkin, S. M. -541

Ivanov-Omskii, V. I., and B. T. Kolomiets. Electrical Properties of an Equimolecular InSb-GaSb Alloy. -363

Iveronova, V. I., see Zvyagina, A. P. -108

Ivko, V. M., see Sapogin, L. G. -1346

Izumov, Yu. A., and G. V. Skrotskii, Spin Resonance by Conduction Electrons in Ferromagnetic Metals. -1597

Izyumova, T. G., see Skrotskii, G. V. -1572

Izyumova, T. G., see Skrotskii, G. V. -2190

Kalabin, M. M., and P. V. Sharavskii, The Surface Conductivity of Cuprous Oxide Rectifiers. -785

Kalabukhov, N. P., and V. G. Sidyakin. Measurement of Photocurrent-Carrier Mobility in Additively Colored KCl Crystals. -2309

Kalashnikov, S. G., and I. A. Kurova, The Electrical Conductivity of Germanium at Low Temperatures. -1756

Kalashnikov, S. G., and A. K. Mednikov. The Effect of a Copper-Impurity Atmosphere at Dislocations in Germanium on Recombination. -1847

Kalashnikov, S. G., and A. I. Morozov. Investigation of Trapping at Copper Atoms in Germanium. -2505

Kalashnikov, S. G., and K. P. Tissen. Capture and Recombination at Multielectron Capture Centers in Semiconductors. -2443

Kamadzhiev, P. R., see Elistratov, A. M. -2821

Kamysheva, L. N., The Problem of Replacement of a Titanium Ion by a Silicon Ion in Polycrystalline Barium Titanate. -909

Kapitsa, M. L., S. A. Fridrikhov, and A. R. Shul'man, Characteristic Energy Losses on Reflection of Electrons from Monocrystals of Alkali Halides. -482

Kapitsa, M. L., see Shul'man, A. R. -2498

Kaplyanskii, A. A., see Gross, E. F. -353

Kaplyanskii, A. A., see Gross, E. F. -1518

Kaplyanskii, A. A., see Gross, E. F. -2637

Karasik, V. R., and G. B. Kurganov. The Carrier-Density Effect in Germanium. -2313

Karmen, K. N., The Effect of X-ray Irradiation on the Anomalous Properties of Rochelle Salt. -629

Karmen, K. N., Effect of a Constant Electric Field on the Hysteresis of Rochelles Salt. -1514

Karpechenko, V. G., see Grechanik, L. A. -1908

Kashukeev, N. T., see Golovin, B. M. -911

Kesamanly, F. P., see Emel'yanenko, O. V. -1356

Kessel', A. R., The Ultrasonically Stimulated Spin Echo Effect. -1751

Kharlamova, T. E., and G. F. Kholuyanov. Electrical Properties of Alloyed p-n Junctions in Silicon Carbide. -397

Khodakov, A. L., Dielectric Properties of Finely Dispersed Barium Titanate. -1904

Kholodar', G. A., see Lisitsa, M. P. -1897

Kholuyanov, G. F., Photoelectric Properties of Alloy p-n Junctions in Silicon Carbide. -1722

Kholuyanov, G. F., see Kharlamova, T. E. -397

Kholuyanov, G. F., see Pasynkov, V. V. -403
Khozov, G. V., see Ryvkin, S. M. -1963
Khutsishvili, G. R., see Buishvili, L. L. -1524
Khvostenko, G. I., see Ioffe, V. A. -475
Kirvalidze, I. D., The Effect of Heat Treatment on the Photo-Emf in Cuprous Oxide. -1043
Kirvalidze, I. D., and V. F. Zhukov, Concerning the Effect of Heat Treatment on the Electrical Properties of p-Type Silicon. -537
Kislyi, P. S., and G. V. Samsonov, Diffusion of Boron in Carbon. -1563
Klimin, A. I., B. N. Seykh, and I. L. Sokol'skaya, Concerning Laws Governing Field Emission in Semiconductors. -1673
Klinger, M. I., Theory of Piezoresistance in Bi_2Te_3. -1231
Klinger, M. I., Use of the Theory of Damping in Calculations of Kinetic Coefficients. -2747
Klochikhin, A. A., see Stekhanov, A. I. -2605
Klyachkin, V. I., A Contribution to the Theory of Phase Transitions in Molecular Crystals. -847
Klyachkin, V. I., Theory of Orientation Ordering of Dipole Crystals. -1263
Klyavin, O. V., Mechanical Properties of Solids at a Temperature of 4.2°K and Below. V. Effect of Preliminary Plastic Deformation on the Mechanical Properties of Aluminum, Copper, and Nickel. -1706
Kocnelaev, B. I., About the Theory of Spin-Lattice Relaxation of Paramagnetic Ions in XY_6 Complexes. -1294
Kogan, Sh. M., On Temperature-Dependent Quantum Green's Functions. -1074
Kogan, Sh. M., and V. B. Sandomirskii, Theory of the Intrinsic Emission of Thermionic Electrons from Semiconductors. -2292
Koikov, S. N., and A. N. Tsikin, Solution of the Problem of Thermal Breakdown of Inhomogeneous Dielectrics. -2655
Kokosh, G. V., and S. S. Sinani, Thermoelectric Properties of Alloys of the Pseudobinary System Sb_2Te_3-Bi_2Te_3. -1012
Kolesnik, L. I., see Iglitsyn, M. I. -1400
Kolomiets, B. T., and Lin Chun-ming, Spectral Distribution of the Internal Photoelectric Effect in the ZnSe-CdSe System. -154
Kolomiets, B. T., and V. M. Lyubin, The Mechanism of Photoconductivity in Amorphous Chalcogenides. -46
Kolomiets, B. T., and T. F. Nazarova, The Role of Impurity in the Conductivity of Vitreous As_2SeTe_3. -159
Kolomiets, B. T., and T. F. Nazarova, Hall Effect in Vitrous Materials of the $Tl_2Se \cdot As_2(Se, Te)_3$ System. II. -369
Kolomiets, B. T., and B. V. Pavlov, Vitreous Semiconductors. VIII. Optical Properties of Glasses of Sulfur Group Compounds of Thallium, Arsenic, and Antimony. -592
Kolomiets, B. T., and V. P. Pozdnev, Vitreous Semiconductors. 7. Viscosity of Vitreous Semiconductors of the As_2Se_3-As_2Te_3 System. -23
Kolomiets, B. T., see Goryunova, N. A. -258
Kolomiets, B. T., see Ivanov-Omskii, V. I. -363
Kolomoets, N. V., and E. A. Popova, Thermoelectric Properties of the Intermetallic Compound $MnAl_3$. -1758
Kolomoets, N. V., see Vedernikov, M. V. -2420
Koloskova, N. G., and U. Kh. Kopvillem, On the Effect of the Internal Electric Field in Nonconducting Paramagnetic Single Crystals on the Two-Particle Spin-Spin Interactions. -1243
Konopleva, R. F., S. M. Ryvkin, and I. D. Yaroshetskii, Concerning the Hole-Capture Cross Section of Defects Produced in Germanium by γ-Irradiation. -533
Konopleva, R. F., see Ryvkin, S. M. -1963
Konopleva, R. F., see Zhdanovich, N. S. -2098
Konorov, P. P., and O. V. Romanov, The Electrical Conductivity of Evaporated Germanium Layers. -1688
Konorov, P. P., and Shevchenko, I. B, Electrical Conductivity and Photoelectric Properties of Cadmium and Zinc Telluride Layers. -1027
Konorov, P. P., and A. N. Sokolov, The Electrical Conductivity and Photoconductivity of Lead Oxide Layers Treated with Sulfur, Selenium, and Tellurium. -1999
Konozenko, I. D., V. I. Ust'yanov, and A. P. Galushka, Conditions Necessary for Gamma-Conductivity in CdS Monocrystals. -1436
Konstantinov, B. P., and L. A. Badenko, An Electrical-Diffusion Study of the Behavior of Indium and Antimony Impurities in Germanium. -2400
Kontsevoi, Yu. A., see Iglitsyn, M. I. -1039
Koptskik, V. A., and L. A. Ermakova, Electric and Elastic Parameters of Cancrinite as Functions of Temperature. -643
Kopvillem, U. Kh., The Theory of Cross Relaxation in Magnetically Dilute Crystals. -1653
Kopvillem, U. Kh., see Koloskova, N. G. -1243
Korenblit, I. Ya., Galvanomagnetic Effects in Bi_2Te_3 with Anisotropic Scattering. -2738
Kornfel'd, M. I., Dispersion of Light in Germanium. -42
Kornfel'd, M. I., The Absorption of Light in Germanium. -163
Kornfel'd, M. I., and D. N. Mirlin, Investigation of the Low-Frequency Conductivity Fluctuations in Germanium which Appear on Illumination. -929

Korovin, L. I., and T. Yu. Bulashevich. Oscillations of the Absorption Coefficient in Tellurium in a Magnetic Field Directed Along the Crystal Optic Axis. -2489

Korsunskii, M. I., N. S. Pastushuk, and G. D. Mokhov. Photoconductivity of Sulfur Layers Treated with Mercury Vapor. -1433

Korsunskii, V. M., and M. P. Lisitsa. Infrared Absorption and Structure of the Hole Band of Tellurium. -1466

Kosevich, A. M., and L. V. Tanatarov. The Possibility of the Formation of Caverns in a Solid Body Through Local Melting. -2676

Kostrygin, V. A., Investigation of the Discharge Lag in NaCl Monocrystals of Small Thickness. -1664

Kosyachenko, L. A., see Pilat, I. M. -1381

Kot, M. V., and I. V. Kretsu. Anisotropy of Certain Electrical Properties of Single Crystals of Zinc Antimonide. -1134

Kot, M. V., see Andronik, I. K. -1022

Kovalev, A. N., see Belova, N.A. -2380

Kovalev, O. V., Possible Changes of the Symmetry O_h^7 During a Second-Order Phase Transition. -1105

Kovalev, O. V., Concerning the Degeneracy of Energy Levels in Crystals. -2279

Kovalichev, O. F., see Shishkin, N. I. -329

Kozlovskii, V. Kh., The Existence of Entropy for Dynamical Systems. -841

Kozlovskii, V. Kh., Dynamic Theory of the Deformable Ionic Lattices of Ferroelectric Crystals. -1566

Krainik, N. N., Ferroelectric and Antiferroelectric Properties of Solid Solutions of $NaNbO_3$-$PbZrO_3$. -633

Krainik, N. N., Comparison of Internal Fields Acting in Certain Ferroelectric and Antiferroelectric Structures of the Perovskite Type. -902

Krainik, N. N., and A. I. Agranovskaya, Antiferroelectric and Ferroelectric Properties of Certain Solid Solutions Containing Pb_2MgWO_6. -63

Krainik, N. N., see Smolenskii, G. A. -2651

Kramareva, S. A., and V. I. Stafeev. The Investigation of Some Properties of "Long" Diodes. -359

Kretsu, I. V., see Kot, M. V. -1134

Krinchik, G. S., A Method of Measuring the Magnetic Properties of Thin Ferromagnetic Surface Layer. -1753

Kristensen, I. K., Experimental Investigation of Two Kelvin Equations. -2356

Krivoglaz, M. A., Theory of the Phonon Thermal Conductivity of a Nonideal Crystal Near a Critical Point on a Curve of Dissociation or of Phase Transition of the Second Kind. -1087

Ksendzov, Ya. M., The Mechanism of Electric Conductivity in Ferromagnetic and Antiferromagnetic Semiconductors. -2474

Kucher, T. I., and K. B. Tolpygo. Structure of the Hole Bands of Alkali Chloride Metals. -2052

Kukharskii, A. A., see Subashiev, V. K. -2406

Kulikov, G. S., see Boltaks, B. I. -187

Kulikov, G. S., see Boltaks, B. I. -2134

Kunin, V. Ya., and A. N. Chikin. Change of the Dielectric Properties of Rutile Ceramics During the Passage of Current and during Heating. -2101

Kurganov, G. B., see Karasik, V. R. -2313

Kurilo, P. M., see Baranskii, P. I. -424

Kurova, I. A., and N. D. Tyapkina. Electrical Conductivity of Germanium with Lithium Impurity at Low Temperatures. -2761

Kurova, I. A., see Kalashnikov, S. G. -1756

Kuvashinskii, E. V., see Aéro, É. L. -1272

Kuznetsov, A. Ya. Semiconducting Tin Dioxide. -30

Kuznetsov, A. Ya., and L. A. Pafomova. Films of Semiconducting ZrO_2. -2289

Kyshinskii, E. V., see Lebedev, G. A. -87

Lagunova, T. S., see Emel'yanenko, O. V. -176

Landsberg, E. G. [with an appendix by V. L. Bonch-Bruevich] The Influence of Geometrical Dimensions of Samples in Measurements of the Diffusion Length Using the Photomagnetic Method. -777

Landsman, A. P., see Gliberman, A. Ya. -1583

Landsman, A. P., see Subashiev, V. K. -2406

Lang, I. G., Application of the Method of the Density Matrix to the Problem of Conductivity Electrons Interacting with Lattice Vibrations. -2077

Lange, V. N., and A. R. Regel', Certain Features of the Dependence of the Forbidden-Band Width and the Carrier Mobility on the Composition of Tellurium-Selenium and Tellurium-Sulfur Solid Solutions. -2173

Larichev, V. N., see Zolotarev, V. F. -1574

Latsh, V. V., N. G. Minaev, and B. Kh. Somin. X-Ray Investigation of the Phase Composition of Ni-Zn-Ferrites with the CoK_α Radiation. -1479

Latsh, V. V., N. G. Minaev, B. Kh. Somin, and N. É. Stepina. Dissolving the Excess of Ferric Oxide in Ni-Zn Ferrite. -1956

Lazarev, A. N., and A.S. Zaitseva. Valent Hydroxyl Vibrations in Ferroelectric KH_2PO_4 and KD_2PO_4 Crystals. -2688

Lazarev, B. G., see Garber, R. I. -991

Lebedev, G. A., and E. V. Kyshinskii. Mechanism of Deformation of Solid Amorphous Polymethylmethacrylate and Polyvinylacetate during Cold Extraction. -87

Lebedev, N. A., see Murin, A. N. -2324

Lepeshinskaya, V. N., and G. B. Stuchinskii. Inelastic Reflection of Electrons and Secondary Electron Emission of Activated CuAlMg Alloy in an Inter-

val of Primary-Electron Energies from 0.5 to 20 kev -1209
Lerner, M. M., see Tareev, B. M. -2217
Levin, B. Ya., see Zhurkov, S. N. -939
Levin, B. Ya., see Zhurkov, S. N. -1853
Levinson, I. B., Exciton Models in the Strong-Binding Approximation. -2330
Likhachev, V. A., see Davidenkov, N. N. -2183
Likhter, A. L., see Sekoyan, S. S. -1748
Lipaeva, G. L., and G. I. Skanavi. Temperature Dependence of ϵ' and ϵ'' of Strontium-Bismuth Titanate and of Barium Titanate at Frequencies of 9400 Mc. -472
Lipnik, A. A., Calculations of the Binding and Decay of the Mott Exciton with Exact Coulomb Functions. I. -1835
Lisitsa, M. P., and G. A. Kholodar'. The Infrared Absorption and the Energy-Band Structure of Cuprous Oxide. -1897
Lisitsa, M. P., see Korsunskii, V. M. -1466
Litovchenko, V. G., and V. I. Lyashenko. Investigation of the Kinetics of Fast Surface States in Germanium. -1442
Litovchenko, V. G., and O. V. Snitko. Surface Properties of Silicon. -554
Litovchenko, V. G., and O. V. Snitko. Long-Term Variations of the Field Effect in Silicon. -748
Lomakina, G. A., see Vodakov, Yu. A. -49
Lomakina, G. A., see Vodakov, Yu. A. -1
Lomakina, G. A., see Vodakov, Yu. A. -11
Lomonosov, I. I., and Yu. A. Nemilov. Effect of an Electric Field on the Scintillation Process in CsI(Tl). -1476
Lozovskii, V. N., On the Distribution of Relaxation Times for Thermal-Ionic Polarization. -2263
Lur'e, B. G., see Banasevich, S. N. -72
Lur'e, B. G., see Makarov, L. L. -79
Lur'e, B. G., see Murin, A. N. -2324
Lyashenko, V. I., N. S. Chernaya, and A. B. Gerasimov. The Energy Distribution of Surface Electron States for a Pure Germanium Surface With and without the Presence of Adsorbed Oxygen. -2158
Lyashenko, V. I., see Litovchenko, V. G. -1442
Lyast, I. Ts., Polarization of Ionic Crystals Containing Relaxing Defects. -1140
Lyast, I. Ts., Interaction of Ions in the Perovskite Lattice. -1153
Lyubin, V. M., see Kolomiets, B. T. -46
Maiko, V. I., see Pilat, I. M. -1381
Makarov, L. L., B. G. Lur'e, and V. N. Malyshev, The Densities of KCl-RbCl Solid Solutions and the Diffusion of Rubidium Ions in These Solid Solutions. -79
Makhov, A. F., The Penetration of Electrons into Solids. I. The Intensity of an Electron Beam. Transverse Paths of Electrons. -1934
Makhov, A. F., The Penetration of Electrons into Solids. II. The Distribution of Electrons in Depth. -1942
Makhov, A. F., The Penetration of Electrons into Solids. III. The Absorption of the Energy of an Electron Beam. -1945
Makhov, A. F., see Vyatskin, A. Ya. -810
Malkin, G. M., see Vergunas, F. I. -2071
Malkovich, R. Sh., Methods of Calculating the Mobility of Impurity Ions in a Solid. -2479
Malkovich, R. Sh., see Boltaks, B. I. -167
Malkovich, R. Sh., see Boltaks, B. I. -2134
Malygin, G. As., see Davidenkov, N. N. -2183
Malyshev, V. N., see Makarov, L. L. -79
Marchuk, P. M., see Borzyak, P. G. -284
Mashkevich, V. S., Higher Approximation in the Ewald Method. -828
Mashkevich, V. S., The Dipole Approximation in the Microscopic Theory of Crystals. I. Lattice Vibrations as Affected by Electronic Dispersion. -2345
Mashkovich, M. D., see Avetikov, V. G. -2225
Maslakovets, Yu. P., see Vodakov, Yu. A. -49
Maslakovets, Yu. P., see Vodakov, Yu. A. -1
Maslakovets, Yu. P., see Vodakov, Yu. A. -11
Maslova, L. V., see Ryvkin, S. M. -1963
Matalygina, Zh. I., see Plotnikov, Yu. I. -2244
Matskevich, T. L., and É. G. Mikhailova. Secondary Electron Emission in Ice and Anthracene Films. -655
Matveev, O. A., see Ryvkin, S. M. -1963
Mazel', E. Z., see Atsarkin, V. A. -1874
Mazurin, O. V., and R. V. Brailovskaya. The Electrical Conductivity of Glasses of the Na_2O-RO-SiO_2 System. -1341
Mednikov, A. K., The Effect of Tin Treatment on the Lifetime of Nonequilibrium Charge Carriers in Germanium. -215
Mednikov, A. K., see Kalashnikov, S. G. -1847
Medvedev, V. S., see Eremenko, V. V. -1428
Melik-Gaikazyan, I. Ya., see Zavadovskaya, E. K. -617
Mel'nikov, A. I., A. V. Morosov, R. B. Sobolevskaya, and A. R. Shul'man. Thermal Electron Emission from Barium Tungstate. -650
Mel'nikov, M. A., see Vorob'ev, A. A. -1814
Mikhailova, É. G., see Matskevich, T. L. -655
Mikhailovskii, V. M., see Garber, R. I. -950
Milevskii, L. S., The Effect of Quenching on the Minority Carrier Lifetime in Silicon. -1931
Milevskii, L. S., A Mechanism for the Introduction of Recombination Centers in Germanium and Silicon During Low-Temperature Quenching. -1980
Milevskii, L. S., see Akimchenko, I. P. -1891

Minaev, N. G., see Latsh, V. V. -1479
Minaev, N. G., see Latsh, V. V. -1956
Mirlin, D. N., Spatial Correlation of Low-Frequency Conductivity Fluctuations in Germanium. -927
Mirlin, D. N., see Kornfel'd, M. I. -929
Mirlin, D. N., see Sochava, L. S. -18
Mironov, A. G., see Bonch-Bruevich, V. L. -454
Miroshnichenkko, L. S., see Borzyak, P. G. -290
Misarova, Anna, Aging of Barium Titanate Single Crystals. 1160
Miselyuk, E. G., see Belyaev, A. D. -208
Miselyuk, E. G., see Vinetskii, R. M. -60
Mitrenin, B. P., see Vinogradova, M. N. -1298
Mizetskaya, I. B., see Vitrikhovskii, N. I. -2301
Mochan, I. V., see Obraztsov, Yu. N. -761
Moizhes, B. Ya., On the Theory of Photocells with a p-n Junction. -202
Moizhes, B. Ya., The Influence of the Temperature Dependence of Physical Parameters on the Efficiency of Thermoelectric Generators and Refrigerators. -671
Moizhes, B. Ya., and G. E. Pikus. On the Theory of a Plasma Thermoelement. -697
Moizhes, B. Ya., see Devyatkova, E.D. -681
Moizhes, B. Ya., see Ioffe, A.F. -2524
Moizhes, B. Ya., see Smirnov, I. A. -1793
Mokhov, G. D., see Korsunskii, M. I. -1433
Morgulis, N. D., and A. G. Naumovets. Application of Thermionic Emission for the Direct Conversion of Heat Energy to Electrical Energy. -501
Morosov, A. V., see Mel'nikov, A. I. -650
Morozov, A. I., Anisotropy of the Surface Breakdown of Germanium in Strong Fields. -578
Morozov, A. I., see Kalashnikov, S. G. -2505
Morozovskii, V. A., see Zingerman, Ya. P. -2030
Moskalenko, S. A., Excitation Absorption of Light in a Cu_2O Crystal. I. Absence of Constant External Fields. -1587
Murin, A. N., B. G. Lur'e, and N. A. Lebedev. Effect of Pressure on Self-Diffusion of Silver Ions in Silver Bromide. -2324
Murin, A. N., see Banasevich, S. N. -72
Myl'nikova, I. E., see Bokov, V. A. -2428
Myuller, R. L., Electrical Conductivity of Solid Ionic-Atomic Valent Substances. IX. Degree of Dissociation and Mobility of Cations in Glasses with One Type of Ion. -1213
Myuller R. L., Electrical Conductivity of Solid Ionic-Atomic Valent Substances. X. Electrical Conductivity of Glasses Containing Two Kinds of Alkali Ions. -1219
Myuller, R. L., Electrical Conductivity of Solid Ionic-Atomic Valent Substances. XI. Degree of Dissociation and Mobility of Cations in Glasses Containing Two Types of Ions. -1224
Nabutovich, I. S., see Andrievskii, A. I. -892
Nadgornyi, É. M., and B. I. Smirnov. The Structure of Copper Microwire. -2707
Nasledov, D. N., see Agaev, Ya. -758
Nasledov, D. N., see Chih-ch'ao, Lien -729
Nasledov, D. N., see Emel'yanenko, O. V. -176
Nasledov, D. N., see Emel'yanenko, O. V. -2188
Nasledov, D. N., and I. A. Feltin'sh, Electrical Conductivity of Gallium Arsenoselenides at High Temperatures. -755
Nasledov, D. N., M. P. Pronina, and S. I. Radautsan, Some Optical Properties of Solid Solutions of Arsenoselenides and Arsenotellurides of Indium. -44
Nasledov, D. N., M. P. Pronina, and Yu. S. Smetannikova. Photosensitivity Spectrum of n-Type Indium Antimonide. -219
Nasledov, D. N., N. N. Smirnova, and B. V. Tsarenkov. Temperature Dependence of Basic Parameters of GaAs Point-Contact Diodes. -2460
Naumov, G. P., see Vodakov, Yu. A. -1
Naumov, G. P., see Vodakov, Yu. A. -11
Naumov, G. P., see Vodakov, Yu. A. -49
Naumovets, A. G., see Morgulis, N. D. -501
Nazarova, T. F., see Kolomiets, B. T. -159
Nazarova, T. F., see Kolomiets, B. T. -369
Nekrasov, M. M., and Yu. M. Poplavko. Ferroelectric Properties of Solid Solutions in the Trinary System $Ba(Ti, Zr, Sn)O_3$. -1521
Nemchenok, R. I., see Shul'man, A. R. -2498
Nemilov, Yu. A., and V. E. Privalova. On the Influence of Alkali Metals Upon the Properties of Antimony Photocathodes. -1189
Nemilov, Yu. A., see Didenko, A. A. -1304
Nemilov, Yu. A., see Lomonosov, I. I. -1476
Nensberg, E. D., see Smirnov, I. A. -1793
Neshpor, V. S., and G. V. Samsonov. Study of the Electrical Conductivity of Silicides of the Transition Metals. -1966
Nikitin, E. N., An Investigation of the Semiconducting Properties in the Silicon-Cobalt System. -588
Nikitin, E. N., Thermoelectric Properties of the Silicon-Chromium System. -2389
Nitsovich, M. V., see Samoilovich, A. G. -343
Noskov, M. M., see Zverev, L. P. -2357
Novikov, S. R., see Grinberg, A. A. -2415
Novikov, S. R., see Ryvkin, S. M. -541
Novikova, S. I., Study of the Thermal Expansion of α-Sn, InSb, and CdTe. -2087
Novikova, S. I., Thermal Expansion of Diamonds between 25 and 750°K. -1464

Novikova, S. I., Thermal Expansion of Germanium at Low Temperatures. -37

Nran'yan, A. A., Computing the Integrals in the Method of Equivalent Orbitals and Evaluating the Valence-Band Parameters for Semiconductors of the $A^{III}B^{V}$ Type. -439

Nran'yan, A. A., Concerning the Zone Structure of Diamond-Type Crystals. -1494

Nudel'man, S. L., To the Editor of Fizika Tverdogo Tela. 2352

Obraztsov, Yu. N., I. V. Mochan, and T. V. Smirnova, Phonon Part of the Transverse Thermomagnetic Nernst Effect in p-Type Germanium. -761

Oksman, Ya. A., and A. V. Burlakov, Concerning the Investigation of the Photoconductivity of Powdered Semiconductors by the Photoelectric Effect Method. 1644

Oksman, Ya. A., and A. V. Burlakov, Photodielectric Properties of Polycrystalline Cadmium Selenide. I. High Temperatures. -1700

Orlov, I. N., see Golovin, B. M. -911

Ormont, B. F., see Godik, É. É. -2680

Orzhevskii, O. B., see Fistul', V. I. -1976

Oskotskii, V. S., On the Possibility of Investigating the Phonon Density Distribution in a Noncubical Crystal with the Help of the Noncoherent Scattering of Neutron. -647

Pafomova, L. A., see Kuznetsov, A. Ya. -2289

Parfen'ev, R. V., I. I. Farbshtein, and S. S. Shalyt. Magnetoelectric Properties of Tellurium. II. The Effect of Annealing on the Temperature Dependence of the Carrier Mobility. -2599

Paritskii, L. G., and S. M. Ryvkin. Effect of Trapping Levels on the Relaxation of Photoconductivity in CdS Monocrystals. -511

Paritskii, L. G., see Arkad'eva, E. N. -1051

Paritskii, L. G., see Grinberg, A. A. -1403

Pastushuk, N. S., see Korsunskii, M. I. -1433

Pasynkov, V. V., G. F. Kholuyanov, and L. K. Chirkin, Concerning the Dynamic Current-Voltage Characteristics of Silicon Carbide Resistors. -403

Patrina, I. B., see Ioffe, V. A. -609

Patskevich, V. M., see Vavilov, V. S. -1301

Pautova, G. N., see Bol'shov, V. G. -1783

Pavlov, B. V., see Kolomiets, B. T. -592

Pavlovskaya, E. D., I. L. Sokol'skaya and Yu. G. Shishkin, Determination of the Activation Energy of the Work Function Stabilization Process of the Gold-Barium System. -1671

Pedyash, É. M., see Subashiev, V. K. -194

Pekar, S. I., and V. L. Strizhevskii, The Theory of the Temperature Dependence of the Dispersion and Excition Absorption of Light in Crystals. -816

Pekar, S. I., and B. E. Tsekvava. The Dispersion of Light in Exciton-Absorption Regions in Cubic Crystals as Affected by the Anisotropy of the Effective Mass of the Exciton. -242

Penin, N. A., see Belova, N. A. -2360

Perestoronin, I. G., see Soltamov, U. B. -21

Perlin, Yu. E., Consideration of the Polaron Effect in the Theory of Multiphonon Thermal Ionization. -222

Perlin, Yu. E., Impurity Fluorescence in Crystals. -1727

Perlin, Yu. E., Inclusion of Radiationless Transitions in the Theory of Impurity Fluorescence. -1738

Petrov, N. N., Ejection of Electrons from Metals by Ions. 1182

Petrov, A. V., see Devytakova, E. D. -681

Petrov, N. N., Secondary Emission from Metallic Surfaces under the Action of Positive Ions. -857

Petrov, N. N., Secondary Emission from Incandescent Metal Bombarded by Cesium and Potassium Ions. 865

Petrov, R. V., see Emel'yanenko, O. V. -2188

Petrov, V. M., Some Properties of Ferroelectrics at 3000 Mc. -905

Petrovykh, N. V., see Grechanik, L. A. -1908

Petrusevich, V. A., and V. M. Sergeeva. Optical and Photoelectric Properties of In_2Te_3. -2562

Petrusevich, V. A., V. M. Sergeeva, and I. A. Smirnov. The Relationship Between Thermal and Optical Properties of In_2Te_3. -2573

Petrusevich, V. A., see Subashiev, V. K. -925

Petrusevich, V. A., see Subachiev, V. K. -1781

Pikus, G. E., and V. B. Fiks. The Analysis of Microimpurities by a Magnetic Resonance Mass Spectrometer. II. Calculation of the Background Current. -2774

Pikus, G. E., see Bir, G. L. -2039

Pikus, G. E., see Fiks, V. B. -58

Pikus, G. E., see Fiks, V. B. -660

Pikus, G. E., see Moizhes, B. Ya. -697

Pilat, L. M., G. S. Borodinets, L. A. Kosyachenko, and V. I. Maiko. Certain Properties of the CdSb-ZnSb System. -1381

Pines, B. Ya., and I. G. Ivanov, "Aftereffect" in Metal Specimens Subjected to Diffusion Creep at High Temperatures. -872

Pines, B. Ya., and A. F. Sirenko, The Calculated and Empirical Values of the Lifetime of Metals and Alloys Under a Load. -942

Piskovoi, V. N., see Bulmistrov, V. M. -589

Pizio, A. S., see Rybalka, V. V. -1604

Plavnik, G. M., and B. M. Rovinskii. Investigation of the Submicroporosity of Low-Absorption Materials by the Method of Multiple Small-Angle Scattering of X-Rays. -994

Plotnikov, Yu. I., and Zh. I. Matalygina. I. Photoelectromotive Forces in Anthracene. -2244
Poberovskaya, I. S., see Ioffe, V. A. -609
Pogodaev, K. N., The Temperature Dependence of the Electrical Conductivity of Diamonds. -1317
Pokatilov, E. P., Scattering of Electrons by Acoustic Oscillations in Hexagonal Crystals. -1973
Poltinnikov, S. A. see Subashchiev, V. K. -1059
Polyakov, L. M., see Garber, R. I. -884
Polyakov, L. M., see Garber, R. I. -984
Poplavko, Yu. M., see Nekrasov, M. M. -1521
Popov, S. N. see Smolenskii, G. A. -2584
Popova, E. A., see Kolomoets, N. V. -1758
Poral-Koshits, E. A., see Vaipolin, A. A. -1500
Potapkov, N. A., and S. V. Tyablikov. On the Theory of the s-d Model. -2433
Potapov, V. I., see Potemkin, A. Ya. -1668
Potekhina, N. D., see Ryvkin, S. M. -541
Potemkin, A. Ya., and V. I. Potapov, Problem of the Interaction between Copper and Antimony in Germanium. -1668
Pozdnev, V. P., see Kolomiets, B. T. -23
Presnov, V. A., and V. F. Synorov. Investigation of the Surface Electrical Conductivity of Single-Crystal Germanium. -357
Privalova, V. E., see Nemilov, Yu. A. -1189
Prochukhan, V. D., see Goryunova, N. A. -161
Prokopalo, O. I., Concerning Methods of Measuring the EMF of High-Voltage Polarization. -280
Pronina, M. P., see Nasledov, D. N. -44
Pronina, M. P., see Nasledov, D. N. -219
Protopopov, O. D., see Gofman, I. I. -1203
Pushkarev, O. E., see Gubanov, A. I. -1607
Rabotnikov, Yu. L., Application of Group-Theory Methods to Study the Lattice Oscillation of Tellurium. -1879
Radautsan, S. I., see Nasledov, D. N. -44
Rashba, É. I., Properties of Semiconductors with an Extremum Loop. I. Cyclotron and Combinational Resonance in a Magnetic Field Perpendicular to the Plane of the Loop. -1109
Rashba, É. I., A Method of Experimentally Testing the Possibility of Employing a Universal Surface Recombination Velocity when Investigating the Kinetics of Photoelectric Processes. -2397
Rashba, É. I., and V. A. Romanov. A Photoelectric Method of Observing Inhomogeneity with Depth in Semiconductors. -2393
Rashba, É. I., see Boiko, I. I. -99
Rashba, É. I., see Boiko, I. I. -1692
Ravich, Yu. I., Concerning the Theory of Photomagnetoelectric Effects in Semiconductors with Complex Energetic Bands. -2107
Razbash, R. Ya., see Bogdanov, S. V. -621
Razbirin, B. S. see Gross, E. F. -2617
Razinskaya, I. N., and E. E. Rylov, Some Problems Concerning the Time Dependence of the Tenacity of Organic Glasses. -878
Razmadze, A. K., see Trofimenko, A. P. -1033
Rebane, K. K., The Relationship Between the Recombination Luminescence and Conductivity Under Nonisothermal Conditions. -252
Regel', A. R., and L. S. Stil'bans. Abram Fedorovich Ioffe. -2377
Regel', A. R., see Andreev, A. A. -2467
Regel', A. R., see Lange, V. N. -2173
Rez, I. S., see Gurevich, V. M. -624
Rez, I. S., see Gurevich, V. M. -638
Roitsin, A. B., Paramagnetic Resonance of Atoms Injected in a Crystal of the Type NaCl. -1528
Romanenko, V. N., Influence of the Concentration Dependence of the Coefficient of Segregation upon the Redistribution of Components in a Binary System with Directed Crystallization. -793
Romanov, O. V., see Konorov, P. P. -1688
Romanov, V. A., see Rashba É. I. -2393
Romanovskii, V. A., and V. V. Tarasov. Heat Capacity of the Trisulfides of Arsenic, Antimony, and Bismuth in Connection with Their Structural and Physicochemical Properties. -1170
Romanovskii, V. A., and V. V. Tarasov. Low-Temperature Heat Capacity and Entropy at 298.1°K of the Sulfides of Elements in Group V of the D. I. Mendeleev Periodic Table. -1176
Romashkin, Yu. P., The Theory of Diffusion During the Plastic Deformation of Metals. I. Review. -2709
Romashkin, Yu. P., The Theory of Diffusion During the Plastic Deformation of Metals. II. General Functional Relations. -2717
Romashkin, Yu. P., The Theory of Diffusion During the Plastic Deformation of Metals. III. Possible Nature of the Phenomenon. -2722
Romashkin, Yu. P., and L. M. Shestopalov. Grain-Boundary Diffusion During the Creep of Copper. -2691
Romashkin, Yu. P., see Shestopalov, L. M. -2664
Rovinskii, B. M., see Plavnik, G. M. -994
Rozenberg, N. Yu., see Avetikov, V. G. -2225
Rozhanskii, V. N., The Problem of Conditions Necessary for Formation and Development of Cracks in Crystals. -978
Rumsh, M. A., Yu. N. Shuvalov, and L. A. Smirnov. On the Influence of Illumination upon the Intensity of X-Ray Reflections from a Cadmium Sulfide Crystal. -341
Rybalka, V. V., and A. S. Pizio. Recombination of Electrons and Holes on Atoms of Copper and Nickel in High-Resistance Germanium. -1604
Rylov, E. E., see Razinskaya, I. N. -878

Rytova, N. S., see Galkin, G. N. -1819
Ryvkin, S. M., The True Lifetime and a Possible Mechanism of the Nonelastic Scattering of the Current Carriers in Semiconductors. -2148
Ryvkin, S. M., A. A. Grinberg, Yu. L. Ivanov, S. R. Novikov, and N. D. Potekhina. Investigation of the Diffusion of Minority Current Carriers in a Magnetic Field. -541
Ryvkin, S. M., R. F. Konopleva, L. V. Maslova, O. A. Matveev, N. B. Strokan, D. V. Tarkhin, and G. V. Khozov. Low-Inertia Germanium Diodes. -1963
Ryvkin, S. M., and I. D. Yaroshetskii. The Influence of Trap Levels on the Relaxation of the Nonequilibrium Conductivity of Germanium Irradiated with γ-Rays. -1771
Ryvkin, S. M., see Arkad'eva, E. N. -1051
Ryvkin, S. M., see Arkad'eva, E. N. -1704
Ryvkin, S. M., see Berkovskii, F. M. -1762
Ryvkin, S. M., see Grinberg, A. A. -1403
Ryvkin, S. M., see Konopleva, R. F. -533
Ryvkin, S. M., see Paritskii, L. G. -511
Ryvkin, S. M., see Zhdanovich, N. S. -2098
Rzhanov, A. V., The Applicability of a Steady-State Photoconductivity Method to Investigation of the Dependence of Surface-Recombination Velocity on the Surface Potential. -2166
Safarov, V. I., see Gross, E. F. -2617
Sal'kov, E. A., and G. A. Fedorus. An Investigation of the Lux-Ampere Characteristics of CdS Monocrystals. -1429
Samoilovich, A. G., and V. D. Iskra. Effect of the Anisotropy of Crystals on the Thermal Vibration of Atoms in Ge and Si. -2517
Samoilovich, A. G., and M. V. Nitsovich. On the Question of the Magnetic Susceptance of Metallic Lithium. -343
Samokhvalov, A. A., and I. G. Fakidov. Galvanomagnetic Properties of a Magnetite Single Crystal in the Temperature Region 0 to 100°C. -386
Samsonov, G. V., see Kislyi, P. S. -1563
Samsonov, G. V., see Neshpor, V. S. -1966
Sandomirskii, V. B., see Kogan, Sh. M. -2292
Sandulova, A. V., and Chang Yueh-ch'ing, Anisotropy of the Diffusion of Zinc in Polycrystalline Cuprous Oxide. -800
Sandulova, A. V., see Andrievskii, A. I. -581
Sanfirova, T. P., see Zhurkov, S. N. -933
Sanfirova, T. P., see Zhurkov, S. N. -939
Sapogin, L. G., and V. M. Ivko. Circuit for Measuring and Recording the Resistance of Semiconductors in Coordinates log $R = f(1/R)$. -1346
Sarbei, O. G., see Borzyak, P. G. -284
Sarbei, O. G., see Borzyak, P. G. -290
Schastlivyi, V. P., see Chizhikov, D. M. -1148
Sedykh, B. N., see Klimin, A. I. -1673
Segal', R. B., see Bronshtein, I. M. -84
Seiidov, Yu. M., see Abakarov, Dzh. I. -2019
Sekoyan, S. S., and A. I. Likhter, The Effect of Pressure on Magnetoelectric Properties of Bismuth. -1748
Senderikhin, I. M., Contribution to the Theory of Germanium Diode Breakdown. -1367
Senderikhin, I. M., and P. V. Sharavskii. The Investigation of the Characteristics of Germanium Diodes. -1359
Sergeeva, V. M., see Averkin, A. A. -319
Sergeeva, V. M., see Petrusevich, V. A. -2562
Sergeeva, V. M., see Petrusevich, V. A. -2573
Sergeeva, V. M., see Zaslavskii, A. I. -2556
Sergeeva, V. M., see Zaslavskii, A. I. -2565
Sergeeva, V. M., see Zhuze, V. P. -2545
Shalyt, S. S., see Parfen'ev, R. V. -2599
Shamovskii, L. M., A. A. Dunina, and M. I. Gosteva. On the Thermal Dissociation Energy of F-Centers in KCl. -2252
Shamro, E. A., Some Peculiarities of the Piezoelectric Effect in Barium Titanate. -1871
Sharavskii, P. V., see Geller, I. Kh. -1310
Sharavskii, P. V., see Kalabin, M. M. -785
Sharavskii, P. V., see Senderikhin, I. M. -1359
Shaskol'skaya, M. P., and A. A. Blistanov. Concerning the Shadowing of Defects in Silver Chloride Crystals. -2025
Shaskol'skaya, M. P., and Yu. Kh. Vekilov. Effect of Ultraviolet and X-Ray Radiation on the Internal Friction of Silver Chloride. -1001
Shchmelev, V. N., see Zimkina, T. M. -1489
Shefmel', I. T., see Burkin, A. L. -267
Sheinkman, M.K., Photoconductivity Mechanism in CdS-Type Single Crystals. -1046
Sheka, V. I., The Symmetry of the Energy Zones for a Spinning Electron. -1096
Shelykh, A. I., see Averkin, A. A. -319
Shelykh, A. I., see Zhuze, V. P. -2545
Shestopalov, L. M., and Yu. P. Romashkin. Diffusion of Silver in Plastically Deformed Copper. -2664
Shestopalov, L. M., see Romashkin, Yu. P. -2691
Shevchenko, I. B., see Konorov, P. P. -1027
Shilo, V. P., see Goryunova, N. A. -258
Shishkin, N. I., The Vitrification of Liquids and Polymers Under Pressure. 5. The Formation of Condensed Glasses. -322
Shishkin, N. I., and O. F. Kovalichev. The Vitrification of Liquids and Polymers under Pressure. 6. The Dependence of the Volume of the Condensed Glasses upon Temperature. -329
Shishkin, Yu. G., see Pavlovskaya, E. D. -1671
Shmelev, G. I., see Airapetyants, S. V. -689

Shneider, A. D., and I. V. Gavrishchak. Structure and Properties of the HgTe-CdTe System. -1865
Shtivel'man, K. Ya., Energy Spectrum of Holes in Diamond-Type Crystals. -464
Shtivel'man, K. Ya., Energy Spectrum for Holes in Diamond-Type Crystals. -598
Shtrum, E. L., Semiconducting Properties of the $AgFeTe_2$ Phase. -1352
Shuba, Yu. A., and I. V. Smirnova. Photoemission of Electrons by Copper and Silver Iodides. -1201
Shul'man, A. R., and D. A. Ganichev, Secondary Electron Emission and Elastic Reflection of Electrons from Germanium Single Crystals at Small Electron Energies. -495
Shul'man, A. R., and É. P. Gel'. On the Color Depth in Alkali Halide Crystals Subjected to Bombardment under Different Angles by Electrons with Energies from 6 to 15 kv. -489
Shul'man, A. R., M. L. Kapitsa, R. L. Nemchenok and E. V. Zelenetskaya. Photoelectric Emission of Systems W-BaO and W-Ba. -2498
Shul'man, A. R., see Kapitsa, M. L. -482
Shul'man, A. R., see Mel'nikov, A. I. -650
Shuppe, G. N., see Gofman, I. I. -1203
Shur, M. Ya., see Zverev, L. P. -2357
Shuvalov, Yu. N., see Rumsh, M. A. -341
Shvartsenau, N. F., Purification of Tellurium by the Zone Melting Method. -797
Sidyakin, V. G., see Kalabukhov, N. P. -2309
Sinani, S. S., see Kokosh, G. V. -1012
Sinyakov, E. V., and E. A. Staflichuk. $BaTiO_3$-Based Solid Solutions of Niobates and Tantalates of Transition Metals. -66
Sirenko, A. F., see Pines, B. Ya. -942
Skanavi, G. I., see Lipaeva, G. L. -472
Skrotskaya, E. G., see Zyryanov, P. S. -1196
Skrotskii, G. V., and T. G. Izyumova. Kerr's Magnetooptical Effect in Ferromagnetic Substances in a Radio-Frequency Field. -1572
Skrotskii, G. V., and T. G. Izyumova. Theory of the Optical Faraday Effect in Ferromagnetic Monocrystals of Garnet in Radio-Frequency Fields.-2190
Skrotskii, G. V., see Izumov, Yu. A. -1597
Smetannikova, Yu. S., see Nasledov, D. N. -219
Smirnov, B. I., see Nadgornyi, E. M. -2707
Smirnov, I. A., B. Ya. Moizhes, and E. D. Nensberg, The Effective Carrier Mass in Lead Selenide. -1793
Smirnov, I. A., see Devyatkova, E. D. -527
Smirnov, I. A., see Devytakova, E. D. -681
Smirnov, I. A., see Devytakova, E. D. -1786
Smirnov, I. A., see Petrusevich, V. A. -2573
Smirnov, I. A., see Zaslavskii, A. I. -2565
Smirnov, L. A., see Rumsh, M. A. -341
Smirnov, L. S., Radiation Defects in Crystals. -1512
Smirnova, I. V., see Shuba, Yu. A. -1201
Smirnova, N. N., see Nasledov, D. N. -2460
Smirnova, T. V., see Obraztsov, Yu. N. -761
Smolenskii, G. A., V. A. Isupov, A. I. Agranovskaya, and N. N. Krainik. New Ferroelectrics of Complex Composition. IV. -2651
Smolenskii, G. A., V. A. Isupov, A. I. Agranovskaya, and S. N. Popov. Ferroelectrics with Diffuse Phase Transitions. -2584
Smorodina, T. P., X-Ray Investigation of the Tellurium-Selenium System. -807
Snitko, O. V., see Litovchenko, V. G. -554
Snitko, O. V., see Litovchenko, V. G. -748
Sobolev, V. V., see Gross, E. F. -379
Sobolevskaya, R. B., see Mel'nikov, A. I. -650
Sochava, L. S., and D. N. Mirlin, The Relationship between Excess Noise in Germanium and Surface Traps. -18
Sokolov, A. N., see Konorov, P. P. -1999
Sokol'skaya, I. L., see Klimin, A. I., -1673
Sokol'skaya, I. L., see Pavlovskaya, E. D. -1671
Soloshenko, I. I., Dependence of the Attenuation Decrement upon the Total Number of Cycles in Fatigue Tests. -1684
Soltamov, U. B., and I. G. Perestoronin, Nonequilibrium Carrier Lifetime in the Surface Layers of CdSe + + Ag Monocrystals. -21
Somin, B. Kh., see Latsh, V. V. -1479
Somin, B. Kh., see Latsh, V. V. -1956
Sorokin, O. M., Photoelectron Emission from Mercury Telluride. -2091
Sorokin, O. V., and B. T. Tuseev, Comparative Investigation of Magnetoconcentration and Photoelectric Methods of Measuring the Surface Recombination Rate. -1391
Stafeev, V. I., Injection Heat Transfer. -406
Stafeev, V. I., see Kramareva, S. A. -350
Staflichuk, E. A., see Sinyakov, E. V. -66
Starodubov, Ya. D., see Gindin, I. A. -968
Starodubov, Ya. D., see Garber, R. I. -991
Stasyuk, I. V., see Glauberman, A. E. -123
Stavitskaya, T. S., and L. S. Stil'bans. Ionized Impurity Scattering of Electrons in Lead Telluride. -1868
Stekhanov, A. I., and M. B. Éliashberg. Raman Scattering of Mixed Crystals of the Alkali Halide Salts. 2096
Stekhanov, A. I., and A. A. Klochikhin. The Structure of the Vibrational Spectrum of the Hydrogen Bond in Certain Crystals. -2605
Stepina, N. É., see Latsch, V. V. -1956
Stil'bans, L. S., see Stavitskaya, T. S. -1868
Stil'bans, L. S., see Ioffe, A. F. -2524
Stil'bans, L. S., see Regel', A. R. -2377

Stil'bans, L. S., see Vinogradova, M. N. -1298
Strakhov, L. P., see Artamonov, O. M. -715
Strizhevskii, V. L., The Theory of the Dispersion and Absorption of Light in Crystals. -1633
Strizhevskii, V. L., see Pekar, S. I. -816
Strokan, N. B., see Berkovskii, F. M. -1762
Strokan, N. B., see Grinberg, A. A. -1394
Strokan, N. B., see Ryvkin, S. M. -1963
Struzhinskii, V. A., High-Level High-Frequency Germanium Triodes. -391
Snuchinskii, G. B., see Lepeshinskaya, V. N. -1209
Subachchiev, V. K., and S. A. Poltinnikov. Determination of Carrier Mobility and Density in the Surface Layer of a Semiconductor. -1059
Subashiev, V. K., Distribution of Losses and the Efficiency of Different Processes in Photoelectric Converters of Solar Energy. -181
Subashiev, V. K., Determination of Recombination Constants from Spectral Characteristic of a Photoelement with a p-n Junction. -187
Subashiev, V. K., G. B. Dubrovskii, and V. A. Petrusevich, Determination of the Recombination Constant and the Depth of a p-n Junction from the Spectral Characteristics of a Photocell. -1781
Subashiev, V. K., A. P. Landsman, and A. A. Kukharskii. Distribution of Phosphorus Atoms During Diffusion in Silicon. -2406
Subashiev, V. K., and E. M. Pedyash. Energy Diagram of a Real Silicon Photocell. -194
Subashiev, V. K., V. A. Petrusevich, and G. B. Dubrovskii. Determination of the Recombination Constants from the Spectral Response of Photoconductivity. 925
Subashiev, V. K., see Berman, L. S. -1768
Subashiev, V. K., see Dubrovskii, G. B. -1418
Synorov, V. F., see Presnov, V. A. -357
Syrkin, L. N., The Theory of Magnetostriction Vibrations with High Excitation Induction. -1714
Tanatarov, L. V., see Kosevich, A. M. -2676
Tarasov, V. V., see Romanovskii, V. A. -1170
Tarasov, V. V. see Romanovskii, V. A. -1176
Tareev, B. M., and M. M. Lerner. A Theory of the Unidirectional Conduction in Aluminum Oxide Films. -2217
Tarkhin, D. V., see Ryvkin, S. M. -1963
Timofeev, V. B., see Gorban', I. S. -1005
Timofeev, V. B., see Gorban', I. S. -1863
Tissen, K. P., see Kalashnikov, S. G. -2443
Tolpygo, K. B., Optical Elastic, and Piezoelectric Properties of Ionic and Valence Crystals with the ZnS-Type Lattice. -2367
Tolpygo, K. B., and O. F. Tomasevich, The Wave Function and Energy of a Band Electron in NaCl. -2765
Tolpygo, K. B., see Demidenko, Z. A. -2452
Tolpygo, K. B., see Genkina, S. M. -2138
Tolpygo, K. B., see Kucher, T. I. -2052
Tomasevich, O. F., see Tolpygo, K. B. -2765
Tomashevskii, É. E., see Zhurkov, S. N. -1853
Tomchuk, P. M., see Dykman, I. M. -1988
Tomkevich, S. L., see Baranskii, P. I. -1551
Torbin, N. M., Partial Breakdown and Emission of Radiation by NaCl Crystals in Strong Electric Fields. -2221
Trofimenko, A. P., G. A. Fedorus, and A. K. Razmadze. Properties of Thermally Induced Conductivity in Single Crystals of CdS. -1033
Trofimenko, A. P., see Boiko, I. I. -99
Troshchenko, V. T., On the Question of Scattering of Energy in Matter. -958
Trubitsyn, V. P., The Equation of State of Metals by a Statistical Method. -820
Tsarenkov, B. V., see Nasledov, D. N. -2460
Tsevkava, B. E., Generalized Fresnel Equations for the Surface of a Crystal Taking Account of Anisotropy in the Effective Exciton Mass. -447
Tsekvava, B. E., see Pekar, S. I. -242
Tsikin, A. N., see Koikov, S. N. -2655
Tuseev, B. T., see Sorokin, O. V. -1391
Tyablikov, S. V., Concerning the Theory of Ferromagnetic Resonance. -332
Tyablikov, S. V., Theory of Ferromagnetic Resonance. II. (General Relations). -1805
Tyablikov, S. V., see Potapkov, N.A. -2433
Tyapkina, N. D., see Kurova, I.A. -2761
Tyutyunnikova, E. V., see Voitsekhovskaya. -2260
Uritskii, Z. I., see Gurevich, L. É. -1123
Ust'yanov, V. I., see Konozenko, I. D. -1436
Vaidanich, V. I., see Dudkin, L. D. -377
Vaidanich, V. I., see Dudkin, L. D. -1384
Vaipolin, A. A., and E. A. Porai-Koshits. Concerning the Structure of Vitreous-Arsenic Sulfur Group Compounds. -1500
Vasil'ev, A. M., Fine Structure of the Paramagnetic-Resonance Spectrum of the Chromium Ion in Chrome Alums, as Affected by Higher Terms. -2009
Vasil'ev, D. M., and G. I. Arkovenko. Role of Microstresses in the Plastic-Deformation of Metals. -507
Vasil'eva, L.V., see Bol'shov, V. G. -1783
Vasilevskaya, V. N., see Belyaev, A. D. -208
Vavilov, V. S., The Absorption of Free Charge Carriers by Infrared Radiation in Silicon. -346
Vavilov, V. S., and K. I. Britsyn, The Effect of a Strong Electric Field on the Absorption of Light by Silicon. -1746

Vavilov, V. S., V. M. Patskevich, B. Ya. Yurkov, and P. Ya. Glazunov. The Effect of Fast-Electron Bombardment on the Electrical Conductivity of Silicon and the Dependence of the Rate of Defect Formation on the Orientation of a Crystal with Respect to the Electron Beam. -1301

Vavilov, V. S., see Galkin, G. N. -1819

Vedernikov, M. V., and N. V. Kolomoets. Thermoelectric Properties of Solid Solutions of Chromium, Vanadium, and Titanium in Nickel. -2420

Vekilov, Yu. Kh., see Shaskol'skaya, M. P. -1001

Vereshchagin, L. F., and E. V. Zubova. Measurement of the Electrical Resistance of Iodine and Black Phosphorus under a Pressure of up to 200,000 Atm. 2473

Vereshchagin, L. F., see Evdokimova, V. V. -1539

Vergunas, F. I., and G. M. Malkin. The Photodielectric Effect in ZnS-Cu, Co-Phosphors. -2071

Viglin, A. S., On the Anisotropy Constants of Ferromagnetic Cubic Crystals. -304

Viglin, A. S., A Quantitative Measure of the Texture of a Polycrystalline Material-Texture Function. -2195

Vinetskii, V. L., On the Lower Quantum State in Current Carriers and Coloration Centers in Ionic and Atomic Crystals. -2287

Vinetskii, R. M., and E. G. Miselyuk, Determination of the Impurity Concentration in Germanium. -60

Vinogradov, V. S., The Effect of Departures from Periodicity of the Charge Distribution in a Crystal Lattice on Dielectric Losses in the Ultrahigh-Frequency Region. -2338

Vinogradova, M. N., O. A. Golikova, B. P. Mitrenin, and L. S. Stil'bans. The Mechanism of Carrier Scattering in p-Type Germanium. -1298

Vitrikhovskii, N. I., and I. B. Mizetskaya. Mixed ZnS · CdS Monocrystals and Some of Their Properties. -2301

Vladimirov, V. I., A Theory of the Condensation of Excess Vacancies during the Cooling of Solids. -145

Vladimirov, V. V., see Glauberman, A. E. -123

Vladimirov, V. I., see Gurevich, L. E. -1613

Vodakov, Yu. A., G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets. A p-n Junction Photocell made of Cadmium Telluride. -1

Vodakov, Yu. A., G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets. Investigation of Surface Layers in Cadmium-Telluride Crystals. -49

Vodakov, Yu. A., G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets, Properties of p-n Junctions in Cadmium Telluride Photocells. -11

Voishvillo, N. A., see Andreev, N. S. -916

Voitsekhovskaya, I. A., I. A. Golubeva, and E. V. Tyutyunnikova. Investigation of Properties of Alkali-Halide Crystals. Dielectric Losses in KCl (Ba) Crystals. -2260

Vonsovskii, S. V., and M. Sh. Giterman. The Many-Electron Theory of Ionic Crystals. -1622

Vorob'ev, A. A., and G. A. Andreev, Determination of the Energy of Breakdown Disintegration of Solid Dielectrics. -896

Vorob'ev, A. A., and B. B. Budylin. Spontaneous Generation of Color Centers in Irradiated Alkali Halide Crystals after Annealing. -615

Vorob'ev, A. A., G. A. Vorob'ev, and M. A. Mel'nikov. Propagation of a Discharge in Single Crystals of NaCl and KCl. -1814

Vorob'ev, G. A., see Vorob'ev, A. A. -1814

Vul, B. M., Impact Ionization and Tunnel Effect in Semiconductors. -2631

Vyatskin, A. Ya., Concerning the Theory of Inelastic Electron Scattering in Solids. -112

Vyatskin, A. Ya., and A. F. Makhov, The Absorption and Range of Electrons in a Solid. -810

Yakovlev, V. A., Absorption of Infrared Radiation by Electrons in p-Type Silicon. -1471

Yakovlev, V. A., Concerning the Absorption of Infrared Radiation in n-Type Silicon. -2354

Yaroshetskii, I. D., see Konopleva, R. F. -533

Yaroshetskii, I. D., see Ryvkin, S. M. -1771

Yuech-ch'ing Chang, see Sandulova, A. V. -800

Yur'ev, V. G., Thermoelectric Properties of a Gaseous Semiconductor. -2602

Yurkevich, M. I., see Andrievskii, A. I. -581

Yurkov, B. Ya., Dependence of the Number of Radiation Defects in Silicon on the Initial Electron Energy.-2412

Yurkov, B. Ya., see Vavilov, V. S. -1301

Zadumkin, S. N., Approximate Calculation of the Surface Energy of Some Semiconductors Having the Structure of Diamond and of Zinc Blende. -803

Zaitseva, A. K., see Gliberman, A. Ya. -1583

Zaitseva, A. S., see Lazarev, A. N. -2688

Zalivadnyi, S. Ya., see Garber, R. I. -950

Zaslavskaya, I. G., The Exciton Examined from the Point of View of Intermediate Binding with Due Ragard to Translation. -2002

Zaslavskii, A. I., and V. M. Sergeeva. The Polymorphism of In_2Te_3. -2556

Zaslavskii, A. I., V. M. Sergeeva, and I. A. Smirnov. Thermal Conductivity of α- and β-Modifications of In_2Te_3. -2565

Zavadovskaya, E. K., M. S. Ivankina, and I. Ya. Malik-Gaikazyan. The Effect of Annealing on the Physical Properties of Alkali Halide Solid Solutions. 617

Zavaritskaya, É. I., Thermal Effects in the Study of the Electrical Conductivity of Germanium in Liquid Helium. -2673

Zaveta, K., Concerning the Measurement of Galvanomagnetic Properties of Ferrites. -96

Zelenetskaya, E. V., see Shul'man, A. R. -2498

Zgaevskii, V. É., see Chanyshev, S. I. -2193

Zhdanovich, N. S., R. F. Konopleva, and S. M. Ryvkin, The Annealing of Defects Formed in n-Germanium by γ-Rays. -2098

Zheludev, I. S., see Gurevich, V. M. -638

Zholkevich, G. A., The Optical and Photoelectric Properties of Zinc Selenide and Telluride. -1009

Zholkevich, G. A., The Mechanism of the Negative Photoconductivity. -2211

Zhukov, V. F., see Kirvalidze, I. D. -537

Zhurkov, S. N., B. Ya. Levin, and T. P. Sanfirova. The Temperature and Time Dependences of the Mechanical Strength of Silver Chloride. -939

Zhurkov, S. N., B. Ya. Levin, and É. E. Tomashevskii. Variation of the Time Necessary to Rupture Solids in High Vacuum as a Function of Stress. -1853

Zhurkov, S. N., and T. P. Sanfirova. A Study of the Time and Temperature Dependences of Mechanical Strength. -933

Zhuze, V. P., V. M. Sergeeva, and A. I. Shelykh. Electrical Properties of Semiconducting In_2Te_3 with Defective Structure. -2545

Zimkina, T. M., and V. N. Shchmelev, Electron Microscope Investigation of the Oxidation Products of PbS. -1489

Zingerman, Ya. P., V. A. Ishchuk, and V. A. Morozovskii, Electronic and Adsorptive Properties of Films of Barium Atoms on Tungsten. -2030

Zlatkis, A. S., see Avetikov, V. G. -2225

Zolotarev, V. F., and V. N. Larichev, On p-n Junctions in Photosensitive Films of PbS. -1574

Zorina, E. L., A Remark Concerning Mooser and Pearson's Rule. -1745

Zubova, E. V., see Vereshchagin, L. F. -2473

Zverev, L.P., M. M. Noskov, and M. Ya. Shur. Concerning the Contour of Exciton Absorption Bands in Cuprous Oxide. -2357

Zvinchuk, R. A., see Elistratov, A. M. -2111

Zvyagina, A. P., and V. L. Iveronova, Characteristic Temperature and Spectrum of Thermal Lattice Vibrations. -108

Zyryanov, P. S., and E. G. Skroutskaya. Interaction of Acoustic Oscillations in Ion and Electron-Ion Plasmas. -1196

SOVIET PHYSICS – SOLID STATE: SUBJECT INDEX FOR VOL. 2, 1960

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Entries will be found under the following headings:

Acoustical Properties and Effects
Band Structure and Theory
Biography
Crystals and Crystal Structure
Deformation
Devices
Dielectrics and Dielectric Phenomena
Diffusion
Dislocations
Editorial
Elasticity and Plasticity
Electrical Conductivity
Electrical Properties and Effects
Electron Beams
Electron Emission and Absorption
Electron Microscopy
Ferroelectric Materials and Properties
Ferromagnetic Materials and Properties
Field Effect
Films, Thin
Gamma Rays
Glass
Hall Effect and Nernst Effect
Infrared Absorption
Instrumentation and Methods
Ionization Phenomena
Ions and Ionic Crystals
Kinetic Phenomena
Letter to the Editor
Liquids
Magnetic Properties and Effects
Mass Spectrometry
Mathematical Methods
Metallurgy
Optical Properties
Photocells and Photoelements
Photoconductivity
Photoelectric Properties and Effects
Photoelectromagnetic Effects
Photomagnetic Effects
Piezoelectric Effects, Materials, and Properties
Plasma Theory
Polymers
Recombination
Resonance
Scattering
Semiconductor Metallurgy
Semiconductor Theory
Spectra
Surface Properties
Thermal Properties and Effects
Thermoelectric Properties and Effects
Vacuum Techniques
X-Rays

Acoustical Properties and Effects

Effect of the Anisotropy of Crystals on the Thermal Vibration of Atoms in Ge and Si. A. G. Samoilovich and V. D. Iskra - 2517

Interaction of Acoustic Oscillations in Ion and Electon-Ion Plasmas. P. S. Zyryanov and E. G. Skrotskaya-1196

Scattering of Electrons by Acoustic Oscillations in Hexagonal Crystals. E. P. Pakatilov-1973

The Relationship Between Excess Noise in Germanium and Surface Traps. L. S. Sochava and D. N. Mirlin-18

The Ultrasonically Stimulated Spin Echo Effect. A. R. Kessel' - 1751

Band Structure and Theory

Band Structure of the Polaron Energy Spectrum. Z. Ya. Evseev - 1107

Calculation of the Energy Spectrum for Strongly Anisotropic Crystals. A. I. Gubanov and A. D. Chevychelov - 1253

Certain Features of the Dependence of the Forbidden-Band Width and the Carrier Mobility on the Composition of Tellurium-Selenium and Tellurium-Sulfur Solid Solutions. V. N. Lange and A. R. Regel' - 2173

Computing the Integrals in the Method of Equivalent Orbitals and Evaluating the Valence-Band Parameters for Semiconductors of the $A^{III}B^{V}$ Type. A. A. Nran'yan - 439

Concerning the Contour of Exciton Absorption Bands in Cuprous Oxide. I. P. Zverev, M. M. Noskov, and M. Ya. Shur - 2357

Exciton Absorption of Light in a Cu_2O Crystal. I. Absence of Constant External Fields. S. A. Moskalenko - 1587

Infrared Absorption and Structure of the Hole Band of Tellurium. V. M. Korsunskii and M. P. Lisitsa - 1466

Investigation of the Symmetry Properties of Energy Bands of Crystals of the SnSe and Sb_2S_3 Type. F. M. Gashimzade - 1856

On the Theory of Amorphous Conductors. A. I. Gubanov - 605

Oscillations of the Absorption Coefficient in Tellurium in a Magnetic Field Directed Along the Crystal Optic Axis. L. I. Korovin and T. Yu. Bulashevich - 2489

Splitting of the Fundamental Absorption Edge of Cu_2O Produced upon Elimination of Band Degeneracy by an Oriented Deformation of the Crystals. E. F. Gross and A. A. Kaplyanskii - 1518

Structure of the Energy Bands in Semiconductors of the $CdIn_2Se_4$ Type. A. I. Gubanov and F. M. Gashimzade - 236

Structure of the Hole Bands of Alkali Chloride Metals. T. I. Kucher and K. B. Tolpygo - 2052

Symmetry of Energy Bands in TlSe-Type Crystals. F. M. Gashimzade - 2700

The Infrared Absorption and the Energy-Band Structure of Cuprous Oxide. M. P. Lisitsa and G. A. Kholodar' - 1897

Theory of the Deformation Potential for Semiconductors with a Complex Band Structure. G. L. Bir and G. E. Pikus - 2039

The Wave Function and Energy of a Band Electron in NaCl. II. K. B. Tolpygo and O. F. Tomasevich - 2765

Valent Hydroxyl Vibrations in Ferroelectric KH_2PO_4 and KD_2PO_4 Crystals. A. N. Lazarev and A. S. Zaitseva - 2688

Biography

Abram Fedorovich Ioffe. A. R. Regel' and L. S. Stil'bans - 2377

Crystals and Crystal Structure

A Contribution to the Theory of Phase Transitions in Molecular Crystals. V. I. Klyachkin - 847

Aging of Barium Titanate Single Crystals. Anna Misarova - 1160

An Investigation of the Long-Wavelength Fundamental Absorption Edge of CdS and ZnSe Polycrystalline Layers at Low Temperatures. E. F. Gross, B. S. Razbirin, and V. I. Safarov - 2617

Anisotropy of Certain Electrical Properties of Single Crystals of Zinc Antimonide. M. V. Kot and I. V. Kretsu - 1134

Anisotropy of Electrical Properties of Single Crystals of Cadmium Antimonide. I. K. Andronik and M. V. Kot - 1022

A Quantitative Measure of the Texture of a Polycrystalline Material-Texture Function. A. S. Viglin - 2195

A Theory of the Condensation of Excess Vacancies during the Cooling of Solids. V. I. Vladimirov - 145

Calculation of the Energy Spectrum for Strongly Anisotropic Crystals. A. I. Gubanov and A. D. Chevychelov - 1253

Characteristic Energy Losses on Reflection of Electrons from Monocrystals of Alkali Halides. M. L. Kapitsa, S. A. Fridrikhov, and A. R. Shul'man - 482

Certain Properties of Thallium Selenide Monocrystals. G. A. Akhundov, G. B. Abdullaev, and G. D. Guseinov - 1378

Concerning the Degeneracy of Energy Levels in Crystals. O. V. Kovalev - 2279

Concerning the Shadowing of Defects in Silver Chloride Crystals. M. P. Shaskol'skaya and A. A. Blistanov - 2025

Concerning the Zone Structure of Diamond-Type Crystals. A. A. Nran'yan - 1494

Conditions Necessary for Gamma-Conductivity in CdS Monocrystals. I. D. Konozenko, V. L. Ust'yanov, and A. P. Galushka - 1436

Effective Fields in Crystals. Yu. V. Bogomolov - 275

Effect of Trapping Levels on the Relaxation of Photoconductivity in CdS Monocrystals. L. G. Paritskii and S. M. Ryvkin - 511

Electrical Properties of Single Crystals of Bismuth and Its Alloys. I. Galvanomagnetic Properties of Pure Bismuth. D. V. Gitsu and G. A. Ivanov - 1323

Electrical Properties of Single Crystals of Bismuth and Its Alloys. II. Galvanomagnetic Properties of Bismuth-Tellurium Alloys (Solid Solutions). D. V. Gitsu and G. A. Ivanov - 1330

Energy Spectrum of Holes in Diamond-Type Crystals. K. Ya. Shtivel'man - 464

Energy Spectrum for Holes in Diamond-Type Crystals. K. Ya. Shtivel'man - 598

Ferroelectric Properties of Monocrystals of New Perovskite Compounds. V. A. Bokov and I. E. Myl'nikova - 2428

Fine Structure of the Fundamental Absorption Edge in Single Crystals of Cadmium Selenide. E. F. Gross and V. V. Sobolev - 379

Galvanomagnetic Properties of a Magnetite Single Crystal in the Temperature Region 0 to 100°C. A. A. Samokhvalov and I. G. Fakidov - 386

Generalized Fresnel Equations for the Surface of a Crystal Taking Account of Anisotropy in the Effective Exciton Mass. B. E. Tsekvava - 447

Impurity Fluorescence in Crystals. Yu. E. Perlin- 1727
Investigation of Properties of Alkali-Halide Crystals. Dielectric Losses in KCl (Ba) Crystals. I. A. Voitsekhovskaya, I. A. Golubeva, and E. V. Tuytyunnikova - 2260
Investigation of Surface Layers in Cadmium-Telluride Crystals. Yu. A. Bodakov, G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets - 49
Investigation of the Discharge Lag in NaCl Monocrystals of Small Thickness. V. A. Kostrygin - 1664
Investigation of the Effect of Certain Factors on Formation of Dislocations During Crystallization and on the Dislocation States in Germanium Monocrystals. A. D. Belyaev, V. N. Vasilevskaya, and E. G. Miselyuk - 208
Investigation of the Influence of Oriented Deformation Upon the Spectrum of the Basic Absorption Edge of Single Cu_2O Crystals. E. F. Gross and A. A. Kaplyanskii - 2637
Investigation of the Photoconductivity-Response Spectrum of CdSe Monocrystals at 77 and 20°K. V. V. Eremenko - 2315
Investigation of the Photoconductivity-Response Spectrum of Mixed $CdS_x \cdot CdSe_{1-x}$ Monocrystals at 77 and 20° K. V. V. Eremenko - 2320
Investigation of the Surface Electrical Conductivity of Single-Crystal Germanium. V. A. Presnov and V. F. Synorov -357
Low-Temperature Recrystallization of Copper. R. I. Garber, I. A. Ginding, B. G. Lazarev, and Ya. D. Starodubov - 991
Measurement of Photocurrent-Carrier Mobility in Additively Colored KCl Crystals. N. P. Kalabukhov and V. G. Sidyakin - 2309
Method for Growing Uniform Monocrystals of Alloyed Semiconductor Materials, Solid Solutions, and Intermetallic Compounds of a Given Composition Determined by the Composition of the Melt. S. V. Airapetyants and G. I. Shmelev - 689
Mixed ZnS · CdS Monocrystals and Some of Their Properties. N. I. Vitrikhovskii and I. B. Mizetskaya - 2301
Nonequilibrium Carrier Lifetime in the Surface Layers of CdSe + Ag Monocrystals. U. B. Soltamov and I. G. Perestoronin - 21
On the Color Depth in Alkali Halide Crystals Subjected to Bombardment under Different Angles by Electrons with Energies from 6 to 15 kv. A. R. Shul'man and E. P. Gel' - 489
On the Influence of Illumination upon the Intensity of X-Ray Reflections from a Cadmium Sulfide Crystal. M. A. Rumsh, Yu. N. Shuvalov, and L. A. Smirnov - 341
On the Lower Quantum State in Current Carriers and Coloration Centers in Ionic and Atomic Crystals. V. L. Vinetskii - 2267
On the Possibility of Investigating the Phonon Density Distribution in a Noncubical Crystal with the Help of the Noncoherent Scattering of Neutons. V. S. Oskotskii - 647
On the Thermal Dissociation Energy of F-Center in KCl. L. M. Shamovskii, A. A. Dunina, and M. I. Gorteva - 2252
Optical, Elastic, and Piezoelectric Properties of Ionic and Valence Crystals with the ZnS-Type Lattice. K. B. Tolpygo - 2367
Optical Properties of CdS Monocrystals. M. S. Brodin - 1926
Photoconductivity Mechanism in CdS-Type Single Crystals. M. K. Sheinkman - 1046
Possible Changes of the Symmetry O_h^7 During a Second-Order Phase Transition. O. V. Kovalev - 1105
Properties of Thermally Induced Conductivity in Single Crystals of CdS. A. P. Trofimenko, G. A. Fedorus and A. K. Razmadze - 1033
Quadrupole Optical Excitation of the Basic State of Excitons on a Cuprous Oxide Crystal. E. F. Gross and A. A. Kaplyanskii - 353
Radiation Defects in Crystals. L. S. Smirnov - 1512
Secondary Electron Emission and Elastic Reflection of Electrons from Germanium Single Crystals at Small Electron Energies. A. R. Shul'man and D. A. Ganichev - 495
Slip at the Boundaries of Twins During Forward and Reverse Twinning of Iron. I. A. Gindin and Ya. D. Starodubov - 968
Spontaneous Generation of Color Centers in Irradiated Alkali Halide Crystals After Annealing. A. A. Vorob'ev and B. B. Budylin - 615
Structural Transformations of Thin Layers of Tungsten. A. I. Andrievskii and I. D. Nabutovich - 892
Structure and Properties of the HgTe-CdTe System. A. D. Shneider and I. V. Gavrishchak - 1865
Study of the Decomposition of a Supersaturated Solid Solution of Copper in Germanium. A. M. Elistratov and P. R. Kamadzhiev - 2621
The Appearance and Liquidation of Heterogeneous Regions in Monocrystals of Solid Solution of (K,Na)Cl. A. M. Elistratov and R. A. Zvinchuk - 2111
The Change in the Microstructure of Uranium on Cyclic Heat Treatment. R. I. Garber, S. Ya. Zalivadnyi, and V. M. Mikhailovskii - 950
The Densities of KCl – RbCl solid Solutions and the Diffusion of Rubidium Ions in These Solid Solutions.

L. L. Makarov, B. G. Lur'e, and V. N. Malyshev - 79

The Dipole Approximation in the Microscopic Theory of Crystals. I. Lattice Vibrations as Affected by Electronic Dispersion. V. S. Mashkevich - 2345

The Dispersion of Light in Exciton-Absorption Regions in Cubic Crystals as Affected by the Anisotropy of the Effective Mass of the Exciton. S. I. Pekar and B. E. Tsekvava - 242

The Effect of Annealing on the Physical Properties of Alkali Halide Solid Solutions. E. K. Zavadovskaya, M. S. Ivankina, and I. Ya. Melik-Gaikazyan - 617

The Effect of Crystallographic Orientation of Silicon on the Properties of Phototransducers. A. Ya. Gliberman and O. P. Fedoseeva - 2306

The Effect of Departures from Periodicity of the Charge Distribution in a Crystal Lattice on Dielectric Losses in the Ultrahigh-Frequency Region. V. S. Vinogradov - 2338

The Effect of Fast-Electron Bombardment on the Electrical Conductivity of Silicon and the Dependence of the Rate of Defect For mation on the Orientation of a Crystal with Respect to the Electron Beam. V. S. Vavilov, V. M. Patskevich, B. Ya. Yurkov, and P. Ya. Glazunov - 1301

The Effect of the Discrete Structure on the Energy, the Effective Mass, and the Dispersion Law of the Polaron. S. M. Genkina and K. B. Tolpygo - 2138

Theory of Elementary Perturbations in Atomic Crystals. A. E. Glauberman, V. V. Vladimirov, and I. V. Stasyuk - 123

Theory of Orientation Ordering of Dipole Crystals. V. I. Klyachkin - 1263

Theory of the Photomagnetic Effect in Cubic Anisotropic Crystals. A. A. Grinberg - 1235

The Polymorphism of In_2Te_3. A. I. Zaslavskii and V. M. Sergeeva - 2556

The Problem of Conditions Necessary for Formation and Development of Cracks in Crystals. V. N. Rozhanskii - 978

The Structure of the Vibrational Spectrum of the Hydrogen Bond in Certain Crystals. A. I. Stekhanov and A. A. Klochikhin - 2605

The Symmetry of the Energy Zones for a Spinning Electron. V. I. Sheka - 1096

The Temperature and Time Dependences of the Mechanical Strength of Silver Chloride. S. N. Zhurkov, B. Ya. Levin, and T. P. Sanfirova - 939

The Theory of Cross Relaxation in Magnetically Dilute Crystals. U. Kh. Kopvillem - 1653

The Theory of the Dispersion and Absorption of Light in Crystals. V. L. Strizhevskii - 1633

The Theory of the Temperature Dependence of the Dispersion and Exciton Absorption of Light in Crystals. S. I. Pekar and V. L. Strizhevskii - 816

Utilization of the Longitudinal and Transverse Magnetoconcentration Effects to Determine the Magnetoconductivity Coefficients in Anisotropic Crystals with Cubic Symmetry. A. A. Grinberg and S. R. Novikov - 2415

Deformation

Diffusion of Silver in Plastically Deformed Copper. L. M. Shestopalov and Yu. P. Romashkin - 2064

Dynamic Theory of the Deformable Ionic Lattices of Ferroelectric Crystals. V. Kh. Kozlovskii - 1566

Grain-Boundary Diffusion During the Creep of Copper. Yu. P. Romashkin and L. M. Shestopalov - 2691

Investigation of the Influence of Oriented Deformations upon the Spectrum of the Basic Absorption Edge of Single Cu_2O Crystals. E. F. Gross and A. A. Kaplyanskii - 2637

Investigations of Ultramicroscopic Inhomogeneities of the Plastic Deformation of Rock Salt. II. R. I. Garber and L. M. Polyakov - 884

Kinetic Theory of Strength. L. E. Gurevich and V. I. Vladimirov - 1613

Mechanical Properties of Solids at a Temperature of 4.2°K and Below. V. Effect of Preliminary Plastic Deformation on the Mechanical Properties of Aluminum, Copper, and Nickel. O. V. Klyavin - 1706

Mechanism of Deformation of Solid Amorphous Polymethylmethacrylate and Polyvinylacetate during Cold Extraction. G. A. Lebedev and E. V. Kyshinskii - 87

Nature of Shear Formation on the Yield Surface of Metals. N. N. Davidenkov and E. I. Brainin - 1642

Role of Microstresses in the Plastic Deformation of Metals. D. M. Vasil'ev and G. I. Arkovenko - 507

Slip at the Boundaries of Twins During Forward and Reverse Twinning of Iron. I. A. Gindin and Ya. D. Starodubov - 968

Splitting of the Fundamental Absorption Edge of Cu_2O Produced upon Elimination of Band Degeneracy by an Oriented Deformation of the Crystals. E. F. Gross and A. A. Kaplyanskii - 1518

The Dispersion and Reestablishment of Contacts Between Microblocks during Plastic Deformation. R. I. Garber, I. A. Gindin, and L. M. Polyakov - 984

Theory of the Deformation Potential for Semiconductors with a Complex Band Structure. G. L. Bir and G. E. Pikus - 2039

The Possibility of the Formation of Caverns in a Solid Body Through Local Melting. A. M. Kosevich and L. V. Tanatarov - 2676

The Theory of Diffusion During the Plastic Deformation of Metals. I. Review. Yu. P. Romashkin - 2709

The Theory of Diffusion During the Plastic Deformation of Metals. II. General Functional Relations. Yu. P. Romashkin - 2717

The Theory of Diffusion During the Plastic Deformation of Metals. III. Possible Nature of the Phenomenon. Yu. P. Romashkin - 2722

Devices

About the Electric Parameters of Some Types of Selenium Rectifiers. I. Kh. Geller and P. V. Sharavskii - 1310

Avalanche Breakdown in a Diode with a Limited Space-Charge Layer. Z. S. Bribnikov - 782

Circuit for Measuring and Recording the Resistance of Semiconductors in Coordinates log R = f (1/T). L. G. Sapogin and V. M. Ivko - 1346

Cobalt-Manganese Semiconducting Bolometers. A. L. Burkin and I. T. Shefmel' - 267

Concerning Efficiency of Cascade Thermogenerators. A. I. Burshtein - 2232

Concerning the Dynamic Current-Voltage Characteristics of Silicon Carbide Resistors. V. V. Pasynkov, G. F. Kholuyanov, and L. K. Chirkin - 403

Concerning the Efficiency of Thermobattery Cooling. A. I. Burshtein - 2236

Contribution to the Theory of Germanium Diode Breakdown. I. M. Senderikhi - 1367

Effect of the Surface Recombination Rate and the Absorption Coefficient on Transient Characteristics of Photodiodes. A. A. Grinberg and N. B. Strokan - 1394

High-Level High-Frequency Germanium Triodes. V. A. Struzhinskii - 391

Influence of Current-Carrier Generation in the Barrier Layer on the Form of the Reverse Branch of the Current-Voltage Characteristics of Germanium Diodes. N. A. Belova, A. N. Kovalev, and N. A. Penin - 2360

Low-Inertia Germanium Diodes. S. M. Ryvkin, R. B. Konopleva, L. V. Maslova, O. A. Matveev, N. B. Strokan, D. V. Tarkhin, and G. V. Khozov - 1963

On Power Application of Thermoelectric Elements. A. F. Ioffe, B. Ya. Moizhes, and L. S. Stil'bans - 2524

On the Theory of a Plasma Thermoelement. B. Ya. Moizhes and G. E. Pikus - 697

Photoelectric Converter Made of Polycrystalline Silicon. A. Ya. Gliberman, A. K. Zaitseva, and A. P. Landsman - 1583

Photoelectric Properties of Alloy p-n Junctions in Silicon Carbide. G. F. Kholuyanov - 1722

Temperature Dependence of Basic Parameters of GaAs Point-Contact Diodes. D. N. Nasledov, N. N. Smirnova, and B. V. Tsarenkov - 2460

Temperature Dependence of the Work Function of Semiconductor Thermionic Cathodes. B. V. Bondarenko - 1916

The Investigation of Some Properties of "Long" Diodes. S. A. Kramareva and V. I. Stafeev - 350

The Investigation of the Characteristics of Germanium Diodes. I. M. Senderikhin and P. V. Sharavskii - 1359

The Surface Conductivity of Cuprous Oxide Rectifiers. M. M. Kalabin and P. V. Sharavskii - 785

The Voltage Sensitivity of Hall-EMF Probes. V. V. Galavanov - 55

Dielectric and Dielectric Phenomena

Changes of the Dielectric Properties of Rutile Ceramics during the Passage of Current and during Heating. V. Ya. Kunin and A. N. Chikin - 2101

Concerning Methods of Measuring the EMF of High-Voltage Polarization. O. I. Prokopalo - 280

Creep of Silver on the Surface of Ceramic Dielectrics. I. E. Balygin - 1558

Determination of the Energy of Breakdown Disintegration of Solid Dielectrics. A. A. Vorob'ev and G. A. Andreev - 896

Dielectric Properties of Finely Dispersed Barium Titanate. A. L. Khodakov - 1904

Electric and Elastic Parameters of Cancrinite as Functions of Temperature. V. A. Koptsik and L. A. Ermakova - 643

Electric Fields and Currents in Dielectrics. E. I. Adirovich - 1282

Investigation of Dielectric Loss and Dielectric Constants of Certain Forms of Ceramic in the Ultrahigh-Frequency Region. V. G. Avetikov, A. S. Zlatkis, M. D. Mashkovich, and N. Yu. Rozenberg - 2225

Investigation of Properties of Alkali-Halide Crystals. Dielectric Losses in KCl(Ba) Crystals. L. A. Voitsekhovskaya, I. A. Golubeva, and E. V. Tyutyunnikova - 2260

On the Distribution of Relaxation Times of Thermal Ionic Polarization. V. N. Lozovskii - 2263

Propagation of a Discharge in Single Crystals of NaCl and KCl. A. A. Vorob'ev, G. A. Vorob'ev, and M. A. Mel'nikov - 1814

Solution of the Problem of Thermal Breakdown of Inhomogeneous Dielectrics. S. N. Kolkov and A. N. Tsikin - 2655

The Effect of Departures from Periodicity of the Charge Distribution in a Crystal Lattice on Dielectric Losses in the Ultrahigh-Frequency Region. V. S. Vinogradov - 2338

Theory of Heat Conductivity of Ferrodielectric Material at Low Temperatures. A. I. Akhiezer and V. G. Bar'yakhtar - 2178

Diffusion

"Aftereffect" in Metal Specimens Subjected to Diffusion Creep at High Temperatures. B. Ya. Pines and I. G. Ivanov - 872

An Electrical-Diffusion Study of the Behavior of Indium and Antimony Impurities in Germanium. B. P. Konstantinov and L. A. Badenko - 2400

Anisotropy of the Diffusion of Zinc in Polycrystalline Cuprous Oxide. A. V. Sandulova and Chang Yueh-ch'ing - 800

Determination of the Effective Charge of Calcium Ions in NaCl + $CaCl_2$ Solid Solutions. S. N. Banasevich, B. G. Lur'e, and A. N. Murin - 72

Diffusion of Antimony in Germanium Alloyed with Aluminum. I. P. Akimchenko and L. S. Milevskii - 1891

Diffusion of Boron in Carbon. P. S. Kislyi and G. V. Samsonov - 1563

Diffusion of Silver in Plastically Deformed Copper. L. M. Shestopalov and Yu. P. Romashkin-2664

Diffusion of Silver into Cuprous Oxide. A. I. Andrievskii, A. V. Sandulova and M. I. Yurkevich - 581

Diffusion, Solubility, and the Effect of Silver Impurities on Electrical Properties of Silicon. B. I. Boltaks and Hsüeh Shih-yin - 2383

Distribution of Phosphorus Atoms During Diffusion in Silicon. V. K. Subashiev, A. P. Landsman, and A. A. Kukharskii - 2406

Effect of Pressure on Self-Diffusion of Silver Ions in Silver Bromide. A. N. Murin, B. G. Lur'e, and N. A. Lebedev - 2324

Electrical Transport of Gold in Silicon. B. I. Boltaks, G. S. Kulikov, and R. Sh. Malkovich - 2134

Grain-Boundary Diffusion During the Creep of Copper. Yu. P. Romashkin and L. M. Shestopalov - 2691

Investigation of the Barrier Capacitance of Diffused p-n Junctions in Silicon. L. S. Berman and V. K. Subashiev - 1768

Investigation of the Diffusion of Minority Current Carriers in a Magnetic Field. S. M. Ryvkin, A. A. Grinberg, Yu. L. Ivanov, S. R. Novikov, and N. D. Potekhina - 541

The Densities of KCl — RbCl Solid Solutions and Diffusion of Rubidium Ions in These Solid Solutions. L. L. Makarov, B. G. Lur'e, and V. N. Malyshev - 79

The Distribution Coefficient of Tin in Selenium. D. M. Chizhikov and V. M. Édel'shtein - 790

The Equation of Diffusion. R. L. Fogel'son - 824

The Influence of Geometrical Dimensions of Samples in Measurements of the Diffusion Length Using the Photomagnetic Method. E. G. Landsberg [with an appendix by V. L. Bonch-Bruevich] - 777

The Theory of Diffusion During the Plastic Deformation of Metals. I. Review. Yu. P. Romashkin - 2709

The Theory of Diffusion During the Plastic Deformation of Metals. II. General Functional Relations. Yu. P. Romashkin - 2717

The Theory of Diffusion During the Plastic Deformation of Metals. III. Possible Nature of the Phenomenon. Yu. P. Romashkin - 2722

Dislocations

Investigation of the Effect of Certain Factors on Formation of Dislocations During Crystallization and on the Dislocation States in Germanium Monocrystals. A. D. Belyaev, V. N. Vasilevskaya, and E. G. Miselyuk - 208

Observation of Dislocations in Tellurium. A. I. Blum - 1509

The Effect of a Copper-Impurity Atmosphere at Dislocation in Germanium on Recombination. S. G. Kalashnikov and A. K. Mednikov - 1847

Editorial

Lenin and Science - 523

Elasticity and Plasticity

A Study of the Time and Temperature Dependence of Mechanical Strength. S. N. Zhurkov and T. P. Sanfirova - 933

Dependence of the Attenuation Decrement upon the Total Number of Cycles in Fatigue Test. I. I. Soloshenko - 1684

Determination of Interatomic Distance of Solids Uner Pressure. I. Compressibility of Barium and Strontium. V. V. Evdokimova and L. F. Vereshchagin - 1539

Effect of Uniaxially Compressive Mechanical Loading on the Magnetization of Certain Ferrites. Ya. M. Bekker - 1546

Electric and Elastic Parameters of Cancrinite as Functions of Temperature. V. A. Koptsik and L. A. Ermakova - 643

Fundamental Equations of the Theory of Elastic Media with Rotationally Interacting Particles. É. L. Aero and E. V. Kuvshinskii - 1272

Measurement of Residual Stresses in Electrolytic Deposits. N. N. Davidenkov - 2595

Mechanical Properties of Solids at a Temperature of 4.2°K and Below. V. Effect of Preliminary Plastic Deformation on the Mechanical Properties of Aluminium, Copper, and Nickel. O. V. Klyavin - 1706

Optical, Elastic, and Piezoelectric Properties of Ionic and Valence Crystals with the ZnS-Type Lattice. K. B. Tolpygo - 2367
Role of Microstresses in the Plastic Deformation of Metals. D. M. Vasil'ev and G. I. Arkovenko - 507
The Calculated and Empirical Values of the Lifetime of Metals and Alloys Under a Load. B. Ya. Pines and A. F. Sirenko - 942
The Problem of Conditions Necessary for Formation and Development of Cracks in Crystals. V. N. Rozhanskii - 978
The Temperature and Time Dependences of the Mechanical Strength of Silver Chloride. S. N. Zhurkov, B. Ya. Levin, and T. P. Sanfirova - 939
Variation of the Time Necessary to Rupture Solids in High Vacuum as a Function of Stress. S. N. Zhurkov, B. Ya. Levin and E. E. Tomashevskii - 1853

Electrical Conductivity

An Investigation of the Conductivity Induced in Thin Zinc Sulfide Layers. A. A. Didenko, Yu. A. Nemilov, and V. I. Fomina - 1304
An Investigation of the Semiconducting Properties in the Silicon-Cobalt System. E. N. Nikitin - 588
Application of the Method of the Density Matrix to the Problem of Conductivity Electrons Interacting with Lattice Vibrations. I. G. Lang - 2077
Certain Properties of Thallium Selenide Monocrystals. G. A. Akhundov, G. B. Abdullaev, and G. D. Guseinov - 1378
Electrical Conductivity and Photoelectric Properties of Cadmium and Zinc Telluride Layers. P. P. Konorov and I. B. Shevchenko - 1027
Electrical Conductivity of Gallium Arsenoselenides at High Temperatures. D. N. Nasledov and I. A. Feltin'sh - 755
Electrical Conductivity of Germanium with Lithium Impurity at Low Temperatures. I. A. Kurova and N. D. Tyapkina - 2761
Electricl Conductivity of Liquid Selenium in Strong Electric Fields. A. A. Andreev and A. R. Regel' - 2467
Electrical Conductivity of Solid Ionic-Atomic Valent Substances. IX. Degree of Dissociation and Mobility of Cations in Glasses with One Type of Ion. R. L. Myuller - 1213
Electrical Conductivity of Solid Ionic-Atomic Valent Substances. X. Electrical Conductivity of Glasses Containing Two of Alkali Ions. R. L. Myuller - 1219
Electrical Conductivity of Solid Ionic-Atomic Valent Substances. XI. Degree of Dissociation and Mobility of Cations in Glasses Containing Two Types of Ions. R. L. Myuller - 1224
Electrical Conductivity of Valence Semiconductors at Low Temperatures in Strong Electric Fields. V. A. Chuenkov - 734
Forward Current-Voltage Characteristics of a Barrier Layer in a Germanium p-n Junction. F. M. Berkovskii, S. M. Ryvkin, and N. B. Strokan - 1762
Influence of the Electric Field on the Electrical Conductivity, Hall Coefficient, and Magnetoresistance of n-Type InSb in Low Temperatures. Lien Chih-ch'ao and D. N. Nasledov - 729
Injection Phenomenon during Flow of Current Through a Nonhomegeneous Semiconductor. Z. A. Demidenko and K. B. Tolpygo - 2452
Investigation of the Low-Frequency Conductivity Fluctuations in Germanium which Appear on Illumination. M. I. Kornfel'd and D. N. Mirlin - 929
Investigation of the Surface Electrical Conductivity of Single-Crystal Germanium. V. A. Presnov and V. F. Synorov - 357
Nature of the Chemical Bonds and Electrical Conductivity of Compounds of the Structure Type of FeS_2. L. D. Dudkin and Vaidanich - 1384
On the Theory of the s-d Model. N. A. Potapkov and S. V. Tyablikov - 2433
Spatial Correlation of Low-Frequency Conductivity Fluctuations in Germanium. D. N. Mirlin - 927
Study of the Electrical Conductivity of Silicides of the Transition Metals. V. S Neshpor and G. V. Samsonov - 1966
The Conductivity of p-n Junctions in the Reverse Direction. V. I. Fistul' and O. B. Orzhevskii - 1976
The Effect of Fast-Electron Bombardment on the Electrical Conductivity of Silicon and the dependence of the Rate of Defect Formation on the Orientation of a Crystal with Respect to the Electron Beam. V. S. Vavilov, V. M. Patskevich, B. Ya. Yrkov, and P. Ya. Glazunov - 1301
The Electrical Conductivity and Photoconductivity of Lead Oxide Layers Treated with Sulfur, Selenium, and Tellurium. P. P. Konorov and A. N. Sokolov - 1999
The Electrical Conductivity of Evaporated Germanium Layers. P. P. Konorov and O. V. Romanov - 1688
The Electrical Conductivity of Germanium at Low Temperatures. S. G. Kalashnikov and I. A. Kurova - 1756
The Electrical Conductivity of Glasses of the $Na_2O - RO - SiO_2$ System. O. V. Mazurin and R. V. Brailovskaya - 1341
The Electrical Conductivity of Sodium Aluminosilicate Glasses. V. A. Ioffe and G. I. Khvostenko - 475

The Influence of Omnidirectional Pressure upon the Electrical Conductivity and Thermal Electromotive Force of In_2Te_3. A. A. Averkin, V. M. Sergeeva, and A. I. Shelykh - 319

The Mechanism of Electric Conductivity in Ferromagnetic and Antiferromagnetic Semiconductors. Ya. M. Ksendzov - 2474

The Nature of the Electrical Conductivity of Certain Compounds of Transition Metals with $CuAl_2$-Type Lattices. L. D. Dudkin and V. I. Vaidanich - 377

Theory of Electrical Conductivity of Antiferromagnetic Polar Crystals. M. Sh. Giterman and Yu. P. Irkhin - 134

Theory of the Unidirectional Conduction in Aluminum Oxide Films. B. M. Tareev and M. M. Lerner - 2217

The Relationship Between the Recombination Luminescence and Conductivity Under Nonisothermal Conditions. K. K. Rebane - 252

Thermal Effects in the Study of the Electrical Conductivity of Germanium in Liquid Helium. É. I. Zavaritskaya - 2673

The Role of Impurity in the Conductivity of Vitreous As_2SeTe_3. B. T. Kolomiets and T. F. Nazarova - 159

The Symmetry of the Energy Zones for a Spinning Electron. V. I. Sheka - 1096

The Temperature Dependence of the Electrical Conductivity of Diamonds. K. N. Pogodaev - 1317

Transitional dc Conduction Processes in Ceramic Barium Titanate. V. M. Gurevich and L. S. Rez - 624

Electrical Properties and Effects

An Electrical-Diffusion Study of the Behavior of Indium and Antimony Impurities in Germanium. B. P. Konstantinov and L. A. Bodenko - 2400

Anisotropy of Certain Electrical Properties of Single Crystals of Zinc Antimonide. M. V. Kot and I. V. Kretsu - 1134

Anisotropy of Electrical Properties of Single Crystals of Cadmium Antimonide. I. K. Andronik and M. V. Kot - 1022

Appearance of the EMF in Lead Sulfide Films on Being Irradiated by Slow Electrons. O. M. Artamonov and L. P. Strakhov - 715

Application of Thermionic Emission from the Direct Conversion of Heat Energy to Electrical Energy. N. D. Morgulis and A. G. Naumovets - 501

Certain Properties of the CdSb - ZnSb System. I. M. Pilat, G. S. Borodinets, L. A. Kosyachenko, and V. I. Maiko - 1381

Changes of the Dielectric Properties of Rutile Ceramics during the Passage of Current and during Heating. V. Ya. Kunin and A. N. Chikin - 2101

Concerning the Effect of Heat Treatment on the Electrical Properties of p-Type Silicon. I. D. Kirvalidze and V. F. Zhukov - 537

Determination of the Activation Energy of the Work Function Stabilization Process of the Gold-Barium System. É. D. Pavlovskaya, I. L. Sokol'skaya, and Yu. G. Shishkin - 1671

Diffusion, Solubility, and the Effect of Silver Impurities on Electrical Properties of Silicon. B. I. Boltaks and Hsüeh Shih-yin - 2383

Effect of Electric Field on the Temperature of Electrons, Electrical Conductivity, and Thermionic Emission of Semiconductors. I. Atomic Semiconductors, Development of the Method. I. M. Dykman and P. M. Tomchuk - 1988

Electrical Properties of Alloyed p-n Junctions in Silicon Carbide. T. E. Kharlamova and G. F. Kholyuanov - 397

Electrical Properties of an Equimolecular InSb – GaSb Alloy. V. L. Ivanov-Omskii and B. T. Kolomiets - 363

Electrical Properties of Certain Semiconducting Oxide Glasses. V. A. Ioffe, I. B. Patrina, and I. S. Poberovskaya - 609

Electrical Properties of Semiconducting In_2Te_3 with Defective Structure. V. P. Zhuze, V. P. Zhuze, V. M. Sergeeva, and A. I. Shelykh - 2545

Electrical Properties of Single Crystals of Bismuth and Its Alloys. I. Galvanomagnetic Properties of Pure Bismuth. D. V. Gitsu and G. A. Ivanov - 1323

Electrical Properties of Single Crystals of Bismuth and Its Alloys. II. Galvanomagnetic Properties of Bismuth-Tellurium Alloys (Solid Solutions). D. V. Gitsu and G. A. Ivanov - 1330

Electrical Transport of Gold in Silicon. B. I. Boltaks, G. S. Kulikov, and R. Sh. Malkovich - 2134

Electrokinetic Effects in Liquid Semiconductors. V. B. Fiks and G. E. Pikus - 58

Investigation of the Discharge Lag in NaCl Monocrystals of Small Thickness. V. A. Kostrygin - 1664

Magnetoelectric Properties of Tellurium. II. The Effect of Annealing on the Temperature Dependence of the Carrier Mobility. R. V. Parfen'ev, I. I. Farbshtein, and S. S. Shalyt - 2599

Measurement of the Electrical Resistance of Iodine and Black Phosphorus under a Pressure of up to 200,000 atm. L. F. Vereshchagin and E. V. Zubova - 2473

Nature of Bulk-Gradient emf Arising in Germanium in the Presence of Current. P. I. Baranskii - 429
Partial Breakdown and Emission of Radiation by NaCl Crystals in Strong Electric Fields. N. M. Torbin - 2221
Polarization of Ionic Crystals Containing Relaxing Defects. I. Ts.Lyast - 1140
Some Electrical Properties of the AlSb-InSb System. Ya. Agaev and D. N. Nasledov - 758
Study of the Decomposition of a Supersaturated Solid Solution of Copper in Germanium. A. M. Elistratov and P. R. Kamadzhiev - 2621
The Effect of Gold on the Electrical Properties of Silicon. B. I. Boltaks, G. S. Kulikov, and R Sh. Malkovich - 167
The Effect of Pressure on Magnetoelectric Properties of Bismuth. S. S. Sekoyan and A. I. Likhter - 1748

Electron Beams

The Effect of Fast-Electron Bombardment on the Electrical Conductivity of Silicon and the Dependence of the Rate of Defect Formation on the Orientation of a Crystal with Respect to the Electron Beam. V. S. Vavilov, V. M. Patskevich, B. Ya. Yurkov, and P. Ya. Glazunov - 1301
The Penetration of Electrons into Solids. I. The Intensity of an Electron Beam. Transverse Paths of Electrons. A. F. Makhov - 1934
The Penetration of Electrons into Solids. II. The Distribution of Electrons in Depth. A. F. Makhov - 1942
The Penetration of Electrons into Solids. III. The Absorption of the Energy of an Electron Beam. A. F. Makhov - 1945

Electron Emission and Absorption

Characteristic Energy Losses on Reflection of Electrons from Monocrystals of Alkali Halides. M. L. Kapitsa, S. A. Fridrikhov, and A. R. Shul'man - 482
Ejection of Electrons from Metals by Ions. N. N. Petrov - 1182
Emission Properties of Silicon Treated in Cesium Vapors. V. G. Bol'shov, L. V. Vasil'eva, and G. N. Pautova - 1783
Inelastic Reflection of Electrons and Secondary Electron Emission of Activated CuAlMg Alloy in an Interval of Primary-Electron Energies From 0.5 to 20 kev. V. N. Lepshinskaya and G. B. Stuchinskii - 1209
Investigation of Electrostatic Emission of Electrons From a Tungsten Emitter in Pulse Operation. I. I. Gofman, O. D. Protopopov, and G. N. Shuppe -1203
On the Color Depth in Alkali Halide Crystals Subjected to Bombardment under Different Angles by Electrons with Energies from 6 to 14 kv. A. R. Shul'man and É. P. Gel' - 489
Photoelectron Emission from Mercury Telluride. O. M. Sorokin - 2091
Photoemission of Electrons by Copper and Silver Iodides. Yu. A. Shuba and I. V. Smirnova - 1201
Secondary Electron Emission and Elastic Reflection of Electrons from Germanium Single Crystals at Small Electron Energies. A. R. Shul'man and D. A. Ganichev - 495
Secondary Electron Emission and Elastic Reflection of Slow Electrons from NaCl Single Crystals. S. A. Fridrikhov - 157
Secondary Electron Emission from Thin Metal Films on an Activated Base. I. M. Bronshtein and R. B. Segal' - 84
Secondary Electron Emission in Ice and Anthracene Films. T. L. Matskevich and É. G. Mikhailova - 655
Secondary Emission from Incandescent Metal Bombarded by Cesium and Potassium Ions. N. N. Petrov - 865
Secondary Emission from Metallic Surfaces under the Action of Positive Ions. N. N. Petrov - 857
Secondary Emission from No. 46 Glass Under the Effect of Positive Ions of Some Gases. G. M. Batanov - 1839
The Absorption and Range of Electrons in a Solid. A. Ya. Vyat-skin and A. F. Makhov - 810
The Effect of Electrons Inelastically Reflected from Various Types of Support on Secondary Electron Emission from Thin NaCl Films. M. B. Gomoyunova and G. A. Ivanov - 294
The Effect of Quenching on the Minority Carrier Lifetime in Silicon. L. S. Milevskii - 1931
Theory of the Intrinsic Emission of Thermionic Electrons from Semiconductors. Sh. M. Kogan and V. B. Sandomirskii - 2292
The Passage of Electrons Through a Rectangular Potential Barrier with a Small Cylindrical Inhomogeneity. N. B. Aizenberg - 1067
Thermal Electron Emission from Barium Tungstate. A. I. Mel'nikov, A. V. Morosov, R. B. Sobolevskaya, and A. R. Shul'man - 650

Electron Microscopy

Electron Microscope Investigation of the Oxidation Products of PbS. T. M. Zimkina and V.N. Shchmelev - 1489

Ferroelectric Materials and Properties

Antiferroelectric and Ferroelectric Properties of Certain Solid Solutions Containing Pb_2MgWO_6. N. N. Krainik and A. I. Agranovskaya - 63

Comparison of Internal Fields Acting in Certain Ferroelectric and Antiferroelectric Structures of the Perovskite Type. N. N. Krainik - 902
Dissolving the Excess of Ferric Oxide in Ni-Zn Ferrite. V. V. Latsh, N. G. Minaev, B. Kh. Somin, and N.E. Stepina - 1956
Dynamic Theory of the Deformable Ionic Lattices of Ferroelectric Crystals. V. Kh. Kozlovskii - 1566
Effect of a Constant Electric Field on the Hysteresis of Rochelle Salt. K. N. Karman - 1514
Ferroelectric and Antiferroelectric Properties of Solid Solutions of $NaNbO_3 - PbZrO_3$. N. N. Krainik - 633
Ferroelectric Properties of Monocrystals of New Perovskite Compounds. V. A. Bokov and I. E. Myl'nikova - 2428
Ferroelectric Properties of Solid Solutions in the Trinary System Ba(Ti, Zr, Sn)O_3. M. M. Nekrasov and Yu. M. Poplavko - 1521
Ferroelectrics with Diffuse Phase Transitions. G. A. Smolenskii, V. A. Isupov, A. I. Agranovskaya, and S. N. Popov - 2584
New Ferroelectrics of Complex Composition. IV. G. A. Smolenskii, V. A. Isupov, A. I. Agranovskaya, and N. N. Krainik - 2651
Some Properties of Ferroelectrics at 3000 Mc. V. M. Petrov - 905
Some Remarks on Phase Transitions of the Second Kind and the Microscopic Theory of Ferroelectric Materials. V. L. Ginzburg - 1824
The Ferroelectric Properties of Strontium-Bismuth Titanate. A. N. Gubkin - 2732
The Nature of a High-Temperature Phase Transition in Some $BaTiO_3$ Solid Solutions. V. S. Bogdanov and R. Ya. Razbash - 621
Valent Hydroxyl Vibrations in Ferroelectric KH_2PO_4 and KD_2PO_4 Crystals. A. N. Lazarev and A. S. Zaitseva - 2688

Ferromagnetic Materials and Properties

A Method of Measuring the Magnetic Properties of Thin Ferromagnetic Surface Layer. G. S. Krinchik - 1753
A Quantitative Measure of the Texture of a Polycrystalline Material-Texture Function. A. S. Viglin - 2195
Concerning the Measurement of Galvanomagnetic Properties of Ferrites. K. Zaveta - 96
Concerning the Theory of Ferromagnetic Resonance. S. V. Tyablikov - 332
Effect of Uniaxially Compressive Mechanical Loading on the Magnetization of Certain Ferrites. Ya. M. Bekker - 1546
Kerr's Magnetooptical Effect in Ferromagnetic Substances in a Radio-Frequency Field. G. V. Skrotskii and T. G. Izyumova - 1572
On the Anisotropy Constants of Ferromagnetic Cubic Crystals. A. S. Viglin-304
Quasi-Classical Theory of Amorphous Ferromagnetics. A. I. Gubanov - 468
Spin Resonance by Conduction Electrons in Ferromagnetic Metals. Yu. A. Izymov and G. V. Skrotskii - 1597
The Mechanism of Electric Conductivity in Ferromagnetic and Antiferromagnetic Semiconductors. Ya. M. Ksendzov - 2474
Theory of Electrical Conductivity of Antiferromagnetic Polar Crystals. M. Sh. Giterman and Yu. P. Irkhin - 134
Theory of Ferromagnetic Resonance. II. General Relations. S. V. Tyablikov - 1805
Theory of the Optical Faraday Effect in Ferromagnetic Monocrystals of Garnet in Radiofrequency Fields. G. V. Skrotskii and T. G. Izyumova - 2190
The Properties of Semiconductors with Extremal Loops. II. Magnetic Susceptibility in a Field Perpendicular to the Plane of the Loop. I. I. Boiko and É. I. Rashba - 1692
The Theory of Spin Waves. M. A. Gintsburg - 833
X-Ray Investigation of the Phase Composition of Ni-Zn-Ferrites with the CoK_α Radiation. V. V. Latsh, N. G. Minaev, and B. Kh. Somin - 1479

Field Effect

Concerning Laws Governing Field Emission in Semiconductors. A. I. Klimin, B. N. Sedykh, and I. L. Sokol'skaya - 1673
Effective Fields in Crystals. Yu. V. Bogomolov - 275
Long-Term Variations of the Field Effect in Silicon. V. G. Litovchenko and O. V. Snitko - 748

Films, Thin

Films of Semiconducting ZrO_2. A. Ya. Kuznetsov and L. A. Pafomova - 2289
Measurement of Residual Stress in Electrolytic Deposits. N. N. Davidenko - 2595
On p-n Junctions in Photosensitive Films of PbS. V. F. Zolotarev and V. N. Larichev - 1574
Secondary Electron Emission from Thin Metal Films on an Activated Base. L. M. Bronshtein and R. B. Segal' - 84
Structural Transformation of Thin Layer of Tungsten. A. I. Andrievskii and I. D. Nabutovich - 892
The Effect of Electrons Inelastically Reflected from Various Types of Support on Secondary Electron Emission from Thin NaCl Films. M. B. Gomoyunova and G. A. Ivanov - 294

Gamma Rays

Concerning the Hole Capture Cross Section of Defects Produced in Germanium by γ-Irradiation. R. F. Konopleva, S. M. Ryvkin, and I. D. Yaroshetskii - 533

Conditions Necessary for Gamma-Conductivity in CdS Monocrystals. I. D. Konozenko, V. L. Ust'-yanov, and A. P. Galushka - 1436

The Annealing of Defects Formed in n-Germanium by γ-Rays. N. S. Zhdanovich, R. G. Konopleva, and S. M. Ryvkin - 2098

The Influence of Trap Levels on the Relaxation of the Nonequilibrium Conductivity of Germanium Irradiated with γ-Rays. S. M. Ryvkin and I. D. Yaroshetskii - 1771

Glass

Concerning the Structure of Vitreous Arsenic Sulfur Group Compounds. A. A. Vaipolin and E. A. Porai-Koshits - 1500

Electrical Conductivity of Solid Ionic-Atomic Valent Substances. IX. Degree of Dissociation and Mobility of Cations in Glasses with One Type of Ions. R. L. Myuller - 1213

Electrical Conductivity of Solid Ionic-Atomic Valent Substances. X. Electrical Conductivity of Glasses Containing Two Kinds of Alkali Ions. R. L. Myuller - 1219

Electrical Conductivity of Solid Ionic-Atomic Valent Substances. XI. Degree of Dissociation and Mobility of Cations in Glasses Containing Two Types of Ions. R. L. Myuller - 1224

Electrical Properties of Certain Semiconducting Oxide Glasses. V. A. Ioffe, L. B. Patrina, and I. S. Poberovskaya - 609

Preparation and Properties of Glassy-Oxide Semiconductors of the $VO_{2.5}$-$PO_{2.5}$-RO_X Type. L. A. Grechanik, N. V. Petrovykh and V. G. Karpechenko - 1908

Secondary Emission from No. 46 Glass Under the Effect of Positive Ions of Some Gases. G. M. Batanov - 1839

Some Problems Concerning the Time Dependence of the Tenacity of Organic Glasses. I. N. Razinskaya - 878

Structural Interpretation of the Anomalous Scattering of Visible Light in Sodium Borosilicate Glasses. N. S. Andreev, V. I. Aver'yanov, and N. A. Voishvillo - 916

The Electrical Coductivity of Glasses of the Na_2O – RO – SiO_2 System. O. V. Mazurin and R. V. Brailovskaya - 1341

The Electrical Conductivity of Sodium Aluminosilicate Glasses. V. A. Ioffe and G. I. Khvostenko 475

The Vitrification of Liquids and Polymers Under Pressure. 5. The Formation of Condensing Glasses. N. I. Shishkin - 322

The Vitrification of Liquids and Polymers under Pressure. 6. The Dependence of the Volume of the Condensed Glasses upon Temperature. N. I. Shishkin and O. F. Kovalichev - 329

Vitreous Semiconductors. 7. Viscosity of Vitreous Semiconductors of the As_2Se_3 – As_2Te_3 System. B. T. Kolomiets and V. P. Pozdnev - 23

Vitreous Semiconductors. 8. Optical Properties Glasses of Sulfur Group Compounds of Thallium, Arsenic, and Antimony. B. T. Kolomiets and B. V. Pavlov - 592

Vitreous Semiconductors. 9. Vitrification in Complex Chalcogenides Based on Arsenic Sulfide and Selenide. N. A. Goryunova, B. T. Kolomiets, and V. P. Shilo - 258

Hall Effect and Nernst Effect

Certain Properties of Thallium Selenide Monocrystals. G. A. Akhundov, G. B. Abdullaev, and G. D. Guseinov - 1378

Hall Effect in Vitreous Materials of the Tl_2Se-$As_2(Se,Te)_3$ System. III. B. T. Kolomiets and T. F. Nazarova - 369

Influence of the Electric Field on the Electrical Conductivity, Hall Coefficient, and Magnetoresistance of n-Type InSb in Low Temperatures. Lien Chih-ch'ao and D. N. Nasledov - 729

Phonon Part of the Transverse Thermomagnetic Nernst Effect in p-Type Germanium. Yu. N. Obraztsov, I. V. Mochan, and T. V. Smirnova - 761

The Carrier-Density Effect in Germanium. V. R. Karasik and G. B. Kurganov - 2313

The Nernst-Ettingshausen Effect in p-Type Gallium Arsenide. O. V. Emel'yanenko, D. N. Nasledov, and R. V. Petrov - 2188

Thermomagnetic Properties of Gallium Antimonide. D. Kh. Amirkhanova - 1019

Infrared Absorption

Absorption of Infrared Radiation by Electrons in p-Type Silicon. V. A. Yakovlev - 1471

Absorption of Infrared Radiation by Semiconductors in an Electric Field. N. V. Fomin - 566

Concerning the Absorption of Infrared Radiation in n-Type Silicon. V. A. Yakovlev - 2354

Infrared Absorption and Structure of the Hole Band of Tellurium. V. M. Korsunskii and M. P. Lisitsa - 1466

Oscillations of the Absorption Coefficient in Tellurium in a Magnetic Field Directed Along the Crystal Optic Axis. L. I. Korovin and T. Yu. Bulashevich - 2489

The Absorption of Free Charge Carriers by Infrared Radiation in Silicon. V. S. Vavilov - 346
The Infrared Absorption and the Energy-Band Structure of Cuprous Oxide. M. P. Lisitsa and G. A. Kholodar' - 1897
Theory of Infrared Absorption in Crystals. L. É. Gurevich and Z. I. Uritskii - 1123

Instrumentation and Methods
A Method for Experimentally Testing the Possibility of Employing a Universal Surface Recombination Velocity when Investigating the Kinetics of Photoelectric Process. É. I. Rashba - 2397
A Photoelectric Method of Observing Inhomogeneity with Depth in Semiconductors. É. I. Rashba and V. A. Romanov - 2393
Comparative Investigation of Magnetoconcentration and Photoelectric Methods of Measuring the Surface Recombination Rate. O. V. Sorokin and B. T. Tuseev - 1391
Concerning a Rapid Method of Precise Measurements of Thermal emf of Semiconductors. O. V. Emel'yanenko and F. P. Kesamanly - 1356
The Photoelectretic State in ZnS and Two New Electrophotographic Processes. B. M. Golovin, N. T. Kashukeev, I. N. Orlov, and V. M. Fridkin - 911

Ionization Phenomena
Consideration of the Polaron Effect in the Theory of Multiphonon Thermal Ionization. Yu. E. Perlin - 222
Effect of an Electric Field on the Scintillation Process in CsI(Tl). I. I. Lomonosov and Yu. A. Nemilov - 1476
Impact Ionization and Tunnel Effect in Semiconductors. B. M. Vul - 2631

Ions and Ionic Crystals
About the Theory of Spin-Lattice Relaxation of Paramagnetic Ions in XY_6 Complexes. B. I. Kochelaev - 1294
Application of Thermionic Emission from the Direct Conversion of Heat Energy to Electrical Energy. N. D. Morgulis and A. G. Naumovets - 501
Effect of Radiation on the Mechanical Properties of Ionic Crystals. B. V. Budylin - 2214
Ejection of Electrons from Metals by Ions. N. N. Petrov - 1182
Exciton Models in the Strong-Binding Approximation. I. B. Levinson - 2330
Interaction of Ions in the Perovskite Lattice. I. Ts. Lyast - 1153
On the Effect of the Internal Electric Field in Nonconducting Paramagnetic Single Crystals on the Two-Particle Spin-Spin Interactions. N. G. Koloskova and U. Kh. Kopvillem - 1243
On the Lower Quantum State in Current Carriers and Coloration Centers in Ionic and Atomic Crystals. V. L. Vinetskii - 2267
Optical, Elastic, and Piezoelectric Properties of Ionic and Valence Crystals with the ZnS-Type Lattice. K. B. Tolpygo - 2367
Polarization of Ionic Crystals Containing Relaxing Defects. I. Ts. Lyast - 1140
Secondary Emission from Incandescent Metal Bombarded by Cesium and Potassium Ions. N. N. Petrov - 865
Secondary Emission from Metallic Surfaces under the Action of Positive Ions. N. N. Petrov - 857
The Many-Electron Theory of Ionic Crystals. S. V. Vonsovskii and M. Sh. Giterman - 1622
The Problem of Replacement of a Titanium Ion by a Silicon Ion in Polycrystalline Barium Titanate. L. N. Kamysheva - 909

Kinetic Phenomena
Electrokinetic Effects in Liquid Semiconductors. V. B. Fiks and G. E. Pikus - 58
Electronic and Adsorptive Properties of Films of Barium Atoms on Tungsten. Ya. P. Zingerman, V. A. Ishchuk, and V. A. Morozovskii - 2030
Investigation of the Kinetics of Fast Surface States in Germanium. V. G. Litovchenko and V. I. Lyashenko - 1442
Investigation of the Kinetics of Infrared Impurity Photoconductivity in CdS Induced by Preliminary Illumination. E. N. Arkad'eva, L. G. Paritskii, and S. M. Ryvkin - 1051
Kinetic Theory of Strength. L. É. Gurevich and V. I. Vladimirov - 1613
The Kinetics of Impurity Photoconductivity and the Effective Cross Sections of Local Centers. É. I. Adirovich - 2123
Use of the Theory of Damping in Calculations of Kinetic Coefficients. M. I. Klinger - 2747

Letter to the Editor
To the Editor of Fizika Tverdogo Tela. S. L. Nudel'man - 2352

Liquids
The Vitrification of Liquids and Polymers under Pressure. 5. The Formation of Condensing Glasses. N. I. Shishkin - 322
The Vitrification of Liquids and Polymers under Pressure. 6. The Dependence of the Volume of the Condensed Glasses upon Temperature. N. I. Shishkin and O. F. Kovalichev - 329

Magnetic Properties and Effects
About the Theory of Spin-Lattice Relaxation of Paramagnetic Ions in XY_6 Complexes. B. I. Kochelaev - 1294

A Method of Measuring the Magnetic Properties of Thin Ferromagnetic Surface Layer. G. S. Krinchik - 1753

Concerning the Measurement of Galvanomagnetic Properties of Ferrites. K. Zaveta - 96

Concerning the Overhauser Effect in Metals with Paramagnetic Impurities. L. L. Buishvili - 2023

Effect of a Magnetic Field on the Heat Conduction of Indium Antimonide. D. Kh. Amirkhanova and R. I. Bashirov - 1447

Electrical Properties of Single Crystals of Bismuth and Its Alloys. II. Galvanomagnetic Properties of Bismuth - Tellurium Alloys (Solid Solutions). D. V. Gitsu and G. A. Ivanov - 1330

Galvanomagnetic Effects in Bi_2Te_3 with Anisotropic Scattering. I. Ya. Korenblit - 2738

Galvanomagnetic Properties of a Magnetite Single Crystal in the Temperature Region 0 to 100°C. A. A. Samokhvalov and I. G. Fakidov - 386

Influence of the Electric Field on the Electrical Conductivity, Hall Coefficient, and Magnetoresistance on n-Type InSb in Low Temperatures. Lien Chih-Ch'ao and D. N. Nasledov - 729

Investigation of the Diffusion of Minority Current Carriers in a Magnetic Field. S. M. Ryvkin, A. A. Grinberg, Yu. L. Ivanov, S. R. Novikov, and N. D. Potekhina - 541

Magnetic Susceptibility of Solid Solutions of Ferrous Oxide in Magnesium Oxide. G. Grossmann and S. M. Ariya - 2208

Magnetic Susceptibility of Solid Solutions of Vanadium Dioxide in Titanium Dioxide. S. M. Ariya and G. Grossmann - 1166

Magnetoelectric Properties of Tellurium. II. The Effect of Annealing on the Temperature Dependence of the Carrier Mobility. R. V. Parfen'ev, I. I. Farbshtein, and S. S. Shalyt - 2599

On the Effect of the Internal Electric Field in Nonconducting Paramagnetic Single Crystals on the Two-Particle Spin-Spin Interactions. N. G. Koloskova and U. Kh. Kopvillem - 1243

On the Question of the Magnetic Susceptance of Metallic Lithium. A. G. Samoilovich and M. V. Nitsovich - 343

On the Theory of Electron Plasma in a Magnetic Field. V. L. Bonch-Bruevich and A. G. Mironov - 454

On the Theory of the s-d Model. N. A. Potapkov and S. V. Tyablikov - 2433

State Diagram and Magnetic Susceptibility of Calcium-Iron Silicates. D. M. Chizhikov and V. P. Schastlivyi - 1148

The Carrier-Density Effect in Germanium. V. R. Karasik and G. B. Kurganov - 2313

The Chemical Potential and the Criterion for Degeneracy of the Conductivity Electrons in a Strong Magnetic Field. A. I. Ansel'm and B. M. Askerov - 2512

The Effect of Pressure on Magnetoelectric Properties of Bismuth. S. S. Sekoyan and A. I. Likhter - 1748

Thermomagnetic Phenomena in Semimetals in a Strong Magnetic Field. A. I. Ansel'm and B. M. Askerov - 2060

The Theory of Cross Relaxation in Magnetically Dilute Crystals. U. Kh. Kopvillem - 1653

The Theory of Magnetostriction Vibrations with High Excitation Induction. L. N. Syrkin - 1714

The Theory of the Magnetic Susceptibility of the Polaron. Dzh. I. Abakarov and Yu. M. Seilidov - 2019

Use of the Theory of Damping in Calculations of Kinetic Coefficients. M. I. Klinger - 2747

Utilization of the Longitudinal and Transverse Magnetoconcentration Effects to Determine the Magnetoconductivity Coefficients in Anisotropic Crystals with Cubic Symmetry. A. A. Grinberg and S. R. Novikov - 2415

Mass Spectrometry

The Analysis of Microimpurities by a Magnetic Resonance Mass Spectrometer. V. B. Fiks and G. E. Pikus - 660

The Analysis of Microimpurities by a Magnetic Resonance Mass Spectrometer. II. Calculation of the Background Current. G. E. Pikus and V. B. Fiks - 2774

Mathematical Methods

A Contribution to the Theory of Phase Transitions in Molecular Crystals. V. I. Klyachkin - 847

Application of Group-Theory Methods to Study the Lattice Oscillations of Tellurium. Yu. L. Rabotnikov - 1879

Calculation of the Binding and Decay of the Mott Exciton with Exact Coulomb Functions. I. A. A. Lipnik - 1835

Computing the Integrals in the Method of Equivalent Orbitals and Evaluating the Valence-Band Parameters for Semiconductors of the $A^{III}B^{V}$ Type. A. A. Nran'yan - 439

Dependence of the Number of Radiation Defects in Silicon on the Initial Electron Energy. B. Ya. Yurkov - 2412

Exciton Models in the Strong-Binding Approximation. I. B. Levinson - 2330

Generalized Fresnel Equations for the Surface of a Crystal Taking Account of Anisotropy in the Effective Exciton Mass. B. E. Tsekava - 447

Higher Approximations in the Ewald Method. V. S. Mashkevich - 828

Investigation of the Accuracy of the Variational Method in the Problem of Impurity Absorption of Light in Silicon. V. M. Buimistrov and V. M. Piskovoi - 569

Methods for Calculating the Mobility of Impurity Ions in a Solid. R. Sh. Malkovich - 2479

On Temperature-Dependent Quantum Green's Functions. S. M. Kogan - 1074

The Dipole Approximation in the Microscopic Theory of Crystals. I. Lattice Vibrations as Affected by Electronic Dispersion. V. S. Mashkevich - 2345

The Effect of the Discrete Structure on the Energy, the Effective Mass, and the Dispersion Law of the Polaron. S. M. Genkina and K. B. Tolpygo - 2138

The Equation of Diffusion. R. L. Fogel'son - 824

The Equation of State of Metals by a Statistical Method. V. P. Trubitsyn - 820

The Exciton Examined from the Point of View of Intermediate Binding with Due Regard to Translation. I. G. Zaslavskaya - 2002

The Existence of Entropy for Dynamical Systems. V. Kh. Kozlovskii - 841

Theory of Elementary Perturbations in Atomic Crystals. A. E. Glauberman, V. V. Vladimirov, and I. V. Stasyuk - 123

The Passage of Electrons Through a Rectangular Potential Barrier with a Small Cylindrical Inhomogeneity. N. B. Aizenberg - 1067

Valence Bond Wave Functions in Certain Crystals. A. I. Gubanov and O. E. Pushkarev - 1607

Metallurgy

"Aftereffect" in Metal Specimens Subjected to Diffusion Creep at High Temperatures. B. Ya. Pines and I. G. Ivanov - 872

A Study of the Time and Temperature Dependences of Mechanical Strength. S. N. Zhurkov and T. P. Sanfirova - 933

$BaTiO_3$-Based Solid Solutions of Niobates and Tantalates of Transition Metals. E. V. Sinyakov and E. A. Stafiichuk - 66

Detection of Formation of Chemical Compounds in Binary Alloys Using the Resistance Welding Method. L. N. Érastov - 256

Dissolving the Excess of Ferric Oxide in Ni-Zn Ferrite. V. V. Latsh, N. G. Minaev, B. Kh. Somin, and N. É. Stepina - 1956

On the Question of the Magnetic Susceptance of Metallic Lithium. A. G. Samoilovich and M. V. Nitsovich - 343

Secondary Emission from Incandescent Metal Bombarded by Cesium and Potassium Ions. N. N. Petrov - 865

Secondary Emission from Metallic Surfaces under the Action of Positive Ions. N. N. Petrov - 857

The Calculated and Empirical Values of the Lifetime of Metals and Alloys under a Load. B. Ya. Pines and A. F. Sirenko - 942

The Structure of Copper Microwire. É. M. Nadgornyi and B. I. Smirnov - 2707

Optical Properties

Absorption of Light by Cuprous Oxide Layers. I. S. Gorban' and V. B. Timofeev - 1005

An Investigation of the Long-Wavelength Fundamental Absorption Edge of CdS and ZnSe Polycrystalline Layers at Low Temperatures. E. F. Gross, B. S. Razbirin, and V. I. Safarov - 2617

A Parallel Study of Depolarization and Electroluminescence of ZnS Photoelectrets. V. M. Fridkin, A. N. Bogatyrev, and É. V. Brakhman - 1952

Dependence of the Photoconductivity and the Intensity of Luminescence of Anthracene Crystals on the Excitation Wavelength. V. V. Eremenko and V. S. Medvedev - 1426

Dispersion of Ligh in Germanium. M. I. Kornfel'd - 42

Impurity Fluorescence in Crystals. Yu. E. Perlin - 1727

Inclusion of Radiationless Transitions in the Theory of Impurity Fluorescence. Yu. E. Perlin - 1738

Instrinsic Optical Absorption in Amorphous and Crystalline Germanium. P. G. Borzyak and R. D. Fedorovich - 39

Investigation of the Accuracy of the Variational Method in the Problem of Impurity Absorption of Light in Silicon. V. M. Buimistrov and V. M. Piskovoi - 569

Kerr's Magnetooptical Effect in Ferromagnetic Substances in a Radio-Frequency Field. G. V. Skrotskii and T. G. Izyumova - 1572

On the Color Depth in Alkali Halide Crystals Subjected to Bombardment under Different Angles by Electrons with Energies from 6 to 15 kv. A. R. Shul'man, and É. P. Gel' - 489

On the Theory of Circular Dichroism in Crystals. V. M. Agranovich - 1085

Optical and Photoelectric Properties of In_2Te_3. V. A. Petrusevich and V. M. Sergeeva - 2562

Optical, Elastic, and Piezoelectric Properties of Ionic and Valence Crystals with the ZnS-Type Lattice. K. B. Tolpygo - 2367

Optical Properties and Photoelectron Emission of Amorphous and Crystalline Germanium Films. P. G. Borzyak and R. D. Fedorovich - 2683

Optical Properties of CdS Monocrystals. M. S. Brodin - 1926

Polarization in the Absorption Spectrum of Cubic Cuprous Oxide. I. S. Gorban' and V. B. Timofeev - 1863
Quadrupole Optical Excitation of the Basic State of Excitons on a Cuprous Oxide Crystal. E. F. Gross and A. A. Kaplyanskii - 353
Some Optical Properties of Solid Solutions of Arsenoselenides and Arsenotellurides of Indium. D. N. Nasledov, M. P. Pronina, and S. I. Radautsan - 44
Spontaneous Generation of Color Centers in Irradiated Alkali Halide Crystals after Annealing. A. A. Vorob'ev and B. B. Budylin - 615
Structural Interpretation of the Anomalous Scattering of Visible Light in Sodium Borosilicate Glasses. N. S. Andreev, V. I. Aver'yanov, and N. A. Voishvillo - 916
The Absorption of Ligh in Germanium. M. I. Kornfel'd - 163
The Dispersion of Light in Exciton-Absorption Regions in Cubic Crystals as Affected by the Anisotropy of the Effective Mass of the Exciton. S. I. Pekar and B. E. Tsekava - 942
The Effect of a Strong Electric Field on the Absorption of Light by Silicon. V. S. Vavilov and K. I. Britsyn - 1746
The Optical and Photoelectric Properties of Zinc Selenide and Telluride. G. A. Zholkevich - 1009
Theory of the Optical Faraday Effect in Ferromagnetic Monocrystals of Garnet in Radiofrequency Fields. G. V. Skrotskii and T. G. Izyumova - 2190
The Relationship between the Recombination Luminescence and Conductivity Under Nonisothermal Conditions. K. K. Rebane - 252
The Relationship between Thermal and Optical Properties of In_2Te_3. V. A. Petrusevich, V. M. Sergeeva, and I. A. Smirnov - 2573
The Theory of the Dispersion and Absorption of Light in Crystals. V. L. Strizhevskii - 1633
The Theory of the Temperature Dependence of the Dispersion and Exciton Absorption of Light in Crystals. S. I. Pekar and V. L. Strizhevskii - 816
Vitreous Semiconductors. VIII. Optical Properties of Glasses of Sulfur Group Compounds of Thallium, Arsenic, and Antimony. B. T. Kolomiets and B. V. Paviov - 592

Photocells and Photoelements

A p-n Junction Photocell Made of Cadmium Telluride Yu. A. Vodakov, G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets - 1
Determination of Recombination Constants from Spectral Characteristic of a Photoelement with a p-n Junction. V. K. Subashiev - 187
Determination of Recombination Constants from the Spectral Characteristics of p-n Junction Photocells. II. G. B. Durovskii and V. K. Subashiev - 1418
Determination of the Recombination Constant and the Depth of a p-n Junction from the Spectral Characteristics of a Photocell. V. K. Subashiev, G. B. Dubrovskii, and V. A. Petrusevich - 1781
Distribution of Losses and the Efficiency of Different Processes in Photoelectric Converters of Solar Energy. V. K. Subashiev - 181
Energy Diagram of a Real Silicon Photocell. V. K. Subashiev and E. M. Pedyash - 194
On the Influence of Alkali Metals Upon the Properties of Antimony Photocathodoes. Yu. A. Nemilov and V. E. Privalova - 1189
On the Theory of Photocells with a p-n Junction. B. Ya. Moizhes - 202
Properties of p-n Junctions in Cadmium Telluride Photocells. Yu. A. Vadakov, G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets - 11
Quantum Efficiency of CdTe p-n Junctions in the Ultraviolet Part of the Spectrum. G. B. Dubrovskii - 536
The Effect of Crystallographic Orientation of Silicon on the Properties of Phototransducers. A. Ya. Gliberman and O. P. Fedoseeva - 2306

Photoconductivity

An Investigation of the Lux-Ampere Characteristics of CdS Monocrystals. E. A. Sal'kov and G. A. Fedorus - 1429
Certain Peculiarities of Photoconductivity of Mercuric Sulfide. N. I. Butsko - 585
Concerning the Investigation of the Photoconductivity of Powdered Semiconductors by the Photoelectric Effect Method. Ya. A. Oksman and A. V. Burlakov - 1644
Dependence of the Photoconductivity and the Intensity of Luminescence of Anthracene Crystals on the Excitation Wavelength. V. V. Eremenko and V.S. Medvedev - 1426
Determination of the Recombination Constants from the Spectral Response of Photoconductivity. V. K. Subashiev, V. A. Petrusevich, and G. B. Dubrovskii - 925
Effect of Trapping Levels on the Relaxation of Photoconductivity in CdS Monocrystals. L. G. Paritskii and S. M. Ryvkin - 511
Induced Infrared Photosensitivity in Certain Semiconductors. E. N. Arkad'eva and S. M. Ryvkin - 1704
Investigation of the Kinetics of Infrared Impurity Photoconductivity in CdS Induced by Preliminary

Illumination. E. N. Arkad'eva, L. G. Paritskii, and S. M. Ryvkin - 1051
Investigation of the Photoconductivity-Response Spectrum of CdSe Monocrystals at 77 and 20° K. V. V. Eremenko - 2315
Investigation of the Photoconductivity-Response Spectrum of Mixed $CdS_x \cdot CdSe_{1-x}$ Monocrystals at 77 and 20° K. V. V. Eremenko - 2320
Measurement of Photocurrent-Carrier Mobility in Additively Colored KCl Crystals. N. P. Kalabukhov and V. G. Sidyakin - 2309
On p-n Junctions in Photosensitive Films of PbS. V. F. Zolotarev and V. N. Larichev - 1574
Photoconductivity of Sulfur Layers Treated with Mercury Vapor. M. I. Korsunskii, N. S. Pastushuk, and G. D. Mokhov - 1433
Photoconductivity Mechanism in CdS-Type Single Crystals. M. K. Sheinkman - 1046
Photosensitivity Spectrum of n-Type Indium Antimonide. D. N. Nasledov, M. P. Pronina, and Yu. S. Smetannikova - 219
Role of Trapping Centers in the Relaxation of Photoconductivity. I. I. Boiko - 1658
The Applicability of a Steady-State Photoconductivity Method of Investigation of the Dependence of Surface-Recombination Velocity on the Surface Potential. A. V. Rzhanov - 2166
The Effect of Trapping Levels in Semiconductors on Steady-State Photoconductivity and Nonequilibrium Carrier Lifetime. A. A. Grinberg, L. G. Paritskii, and S. M. Ryvkin - 1403
The Electrical Conductivity and Photoconductivity of Lead Oxide Layers Treated with Sulfur, Selenium, and Tellurium. P. P. Konorov and A. N. Sokolov - 1999
The Mechanism of Photoconductivity in Amorphous Chalcogenides. B. T. Kolomiets and V. M. Lyubin - 46
The Kinetics of Impurity Photoconductivity and the Effective Cross Sections of Local Centers. É. I. Adirovich - 2123
The Mechanism of the Negative Photoconductivity. G. A. Zholkevich - 2211

Photoelectric Properties and Effects

A Method for Experimentally Testing the Possibility of Employing a Universal Surface Recombination Velocity when Investigating the Kinetics of Photoelectric Processes. É. I. Rashba - 2397
A Photoelectric Method of Observing Inhomogeneity with Depth in Semiconductors. É. I. Rashba and V. A. Romanov - 2393
Concerning the Investigation of the Photoconductivity of Powdered Semiconductors by the Photoelectric Effect Method. Ya. A. Oksman and A. V. Burlakov - 1644
Current-Voltage Characteristics of Photoelectron Emission from Germanium. P. G. Borzyak, P. M. Marchuk, and O. G. Sarbei - 284
Electrical Conductivity and Photoelectric Properties of Cadmium and Zinc Telluride Layers. P. P. Konorov and I. B. Shevchenko - 1027
Optical and Photoelectric Properties of In_2Te_3. V. A. Petrusevich and V. M. Sergeeva - 2562
Optical Properties and Photoelectron Emission of Amorphous and Crystalline Germanium Films. P. G. Borzyak and R. D. Fedorovich - 2683
Photodielectric Properties of Polycrystalline Cadmium Selenide. I. High Temperatures. Ya. A. Oksman and A. V. Burlakov - 1700
Photoelectric Converter Made of Polycrystalline Silicon. A. Ya. Gliberman, A. K. Zaitseva, and A. P. Landsman - 1583
Photoelectric Emission of Systems W-BaO and W-Ba. A. R. Shul'man, M. L. Kapitsa, R. L. Nemchenok, and E. V. Zelenetskaya - 2498
Photoelectric Properties of Alloy p-n Junctions in Silicon Carbide. G. F. Kholuyanov - 1722
Photoelectron Emission from Germanium and Silicon in the Amorphous and Crystalline States. P. G. Borzyak, L. S. Miroshnichenko, and O. G. Sarbei - 290
Photoelectron Emission from Mercury Telluride. O. M. Sorokin - 2091
Properties of p-n Junctions in Cadmium Telluride Photocells. Yu. A. Vodakov, G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets - 11
Spectral Distribution of the Internal Photoelectric Effect in the ZnSe–CdSe System. B. T. Kolomiets and Lin Chun-ming - 154
The Annealing of Defects Formed in n-Germanium by γ-Rays. N. S. Zhdanovich, R. G. Konopleva, and S. M. Ryvkin - 2098
The Effect of Adsorbed Oxygen on the Photo-emf of Lead Sulfide Layers. R. Ya. Berlaga and T. T. Bykova - 2705
The Effect of Heat Treatment on the Photo-emf in Cuprous Oxide. I. D. Kirvalidze - 1043
The Optical and Photoelectric Properties of Zinc Selenide and Telluride. G. A. Zholkevich - 1009
The Photodielectric Effect in ZnS-Cu, Co-Phosphors. F. I. Vergunas and G. M. Malkin - 2071
The Photoelectretic State in ZnS and Two New Electrophotographic Processes. B. M. Golovin, N. T. Kashukeev, I. N. Orlov, and V. M. Fridkin - 911

Photoelectromagnetic Effects

A Parallel Study of Depolarization and Electroluminescence of ZnS Photoelectrets. V. M. Fridkin, A. N. Bogatyrev, and É. V. Brakhman - 1952
Concerning the Theory of Photomagnetoelectric Effects in Semiconductors with Complex Energetic Bands. Yu. I. Ravich - 2107

Photomagnetic Effects
Photosensitivity Spectrum of n-Type Indium Antimonide. D. N. Nasledov, M. P. Pronina, and Yu. S. Smetannikova - 219
The Influence of Geometrical Dimensions of Samples in Measurements of the Diffusion Length Using the Photomagnetic Method. E. G. Landsberg [with an appendix by V. L. Bonch-Bruevich] - 777
Theory of the Anisotropic Photomagnetic Effect in Germanium. A. A. Grinberg - 142
Theory of the Photomagnetic Effect in Cubic Anisotropic Crystals. A. A. Grinberg - 1235
The Photomagnetic Effect in Isotropic Semiconductors and Its Use in Measuring the Lifetime of Minority Current Carriers. A. A. Grinberg - 766
Piezoelectric Effects, Materials, and Properties
Electric and Elastic Parameters of Cancrinite as Functions of Temperature. V. A. Koptsik and L. A. Ermakova - 643
Optical, Elastic, and Piezoelectric Properties of Ionic and Valence Crystals with ZnS-Type Lattice. K. B. Tolpygo - 2367
Some Peculiarities of the Piezoelectric Effect in Barium Titanate. E. A. Shamro - 1871
The Nature of the Transitional Conduction Processes in Piezoelectric Materials. V. M. Gurevich, I. S. Zheludev, and I. S. Rez - 638
Theory of Piezoresistance in Bi_2Te_3. M. I. Klinger - 1231
Plasma Theory
Effect of Electric Field on the Temperature of Electrons, Electrical Conductivity, and Thermionic Emission of Semiconductors. I. Atomic Semiconductors, Development of the Method. I. M. Dykman and P. M. Tomchuk - 1988
Interaction of Acoustic Oscillations in Ion and Electron-Ion Plasmas. P. S. Zyryanov and E. G. Skrotskaya - 1196
On the Theory of Electron Plasma in a Magnetic Field. V. L. Bonch-Bruevich and A. G. Mironov - 454
Polymers
Mechanism of Deformation of Solid Amorphous Polymethylmethacrylate and Polyvinylacetate During Cold Extraction. G. A. Lebedev and E. V. Kyshinskii - 87
The Vitrification of Liquids and Polymers Under Pressure. 5. The Formation of Condensing Glasses. N. I. Shishkin - 322
The Vitrification of Liquids and Polymers Under Pressure. 6. The Dependence of the Volume of the Condensed Glasses Upon Temperature. N. I. Shishkin and O. F. Kovalichev - 329
Recombination
A Mechanism for the Introduction of Recombination Centers in Germanium and Silicon During Low-Temperature Quenching. L. S. Milevskii - 1980
A New Method of Determining the Effective Cross Sections of Local Centers. É. I. Adirovich - 2006
Capture and Recombination at Multielectron Capture Centers in Semiconductors. S. G. Kalashnikov and K. P. Tissen - 2443
Comparative Investigation of Magnetoconcentration and Photoelectric Methods of Measuring the Surface Recombination Rate. O. V. Sorokin and B. T. Tuseev - 1391
Concerning the Hole Capture Cross Section of Defects Produced in Germanium by γ-Irradiation. R. F. Konopleva, S. M. Ryvkin, and I. D. Yaroshetskii - 533
Determination of Recombination Constants from Spectral Characteristic of a Photoelement with a p-n Junction. V. K. Subashiev - 187
Determination of Recombination Constants from Spectral Characteristics of p-n Junction Photocells. II. G. B. Dubrovskii and V. K. Subashiev - 1418
Determination of the Physical Parameters of Recombination Centers Created by Copper in Germanium. M. I. Iglitsyn and Yu. A. Kontsevoi - 1039
Determination of the Recombination Constant and the Depth of a p-n Junction from the Spectral Characteristics of a Photocell. V. K. Subashiev, G. B. Dubrovskii, and V. A. Petrusevich - 1781
Determination of the Recombination Constants from the Spectral Response of Photoconductivity. V. K. Subashiev, V. A. Petrusevich, and G. B. Dubrovskii - 925
Effect of Linear Dislocations on Carrier Recombination in Hole Conducting Germanium. M. I. Iglitsyn and L. I. Kolesnik - 1400
Effect of the Surface Recombination Rate and the Absorption Coefficient on Transient Characteristics of Photodiodes. A. A. Grinberg and N. B. Strokan - 1394
Investigation of Trapping at Copper Atoms in Germanium. S. G. Kalashnikov and A. I. Morozov - 2505
On the Theory of Collison Recombination in Semiconductors. V. L. Bonch-Bruevich and Yu. V. Gulyaev - 431
Recombination of Electrons and Holes on Atoms of Copper and Nickel in High-Resistance Germanium. V. V. Rybalka and A. S. Pizio - 1604
The Applicability of a Steady-State Photoconductivity Method of Investigation of the Dependence of Surface-Recombination Velocity on the Surface Potential. A. V. Rzhanov - 2166
The Effect of a Copper-Impurity Atmosphere at Dislocation in Germanium on Recombination. S. G. Kalashnikov and A. K. Mednikov - 1847

The Influence of Trap Levels on the Relaxation of the Nonequilibrium Conductivity of Germanium Irradiated with γ-Rays. S. M. Ryvkin and I. D. Yaroshetskii - 1771

Volume Recombination in p-Type Silicon Subjected to Heat-Treatment at High-Temperatures. G. N. Galkin - 5

Volume Recombination of Current Carriers in n-Type Silicon Containing Radiation-Induced Structural Defects. G. N. Galkin, N. S. Rytova, and V. S. Vavilov - 1819

Resonance

Concerning the Theory of Ferromagnetic Resonance. S. V. Tyablikov - 332

Fine Structure of the Paramagnetic-Resonance Spectrum of the Chromium Ion in Chrome Alums, as Affected by Higher Terms. A. M. Vasil'ev - 2009

Forbidden Paramagnetic Resonance. L. L. Buishvili and G. R. Khutsishvili - 1524

Paramagnetic Resonance of Atoms Injected in a Crystal of the Type NaCl. A. B. Roitsin - 1528

Properties of Semiconductors with an Extremum Loop, I. Cyclotron and Combinational Resonance in a Magnetic Field Perpendicular to the Plane of the Loop. É. I. Rashba - 1109

Spin Resonance by Conduction Electrons in Ferromagnetic Metals. Yu. A. Izumov and G. V. Skrotskii - 1597

Theory of Ferromagnetic Resonance. II. General Relations. S. V. Tyablikov - 1805

Scattering

Concerning the Theory of Inelastic Electron Scattering in Solids. A. Ya. Vyatskin - 112

Galvanomagnetic Effects in Bi_2Te_3 with Anisotropic Scattering. I. Ya. Korenblit - 2738

Investigation of the Submicroporosity of Low-Absorption Materials by the Method of Multiple Small-Angle Scattering of X-Rays. G. M. Plavnik and B. M. Rovinskii - 994

Ionized Impurity Scattering of Electrons in Lead Telluride. T. S. Stavitskaya and L. S. Stil'bans - 1868

On the Possibility of Investigating the Phonon Density Distribution in a Noncubical Crystal with the Help of the Noncoherent Scattering of Neutrons. V. S. Oskotskii - 647

On the Question of the Scattering of Energy in Matter. V. T. Troshchenko - 958

Raman Scattering of Mixed Crystals of the Alkali Halide Salts. A. I. Stekhanov and M. B. Élashberg - 2096

Scattering of Current Carriers in Gallium Arsenide in the Presence of Strong Degeneracy. O. V. Emel'yanenko, T. S. Lagunova, and D. S. Nasledov - 176

Scattering of Electrons by Acoustic Oscillations in Hexagonal Crystals. E. P. Pokatilov - 1973

The Mechanism of Carrier Scattering in p-Type Germanium. M. N. Vinogradova, O. A. Golikova, B. P. Metrenin, and L. S. Stil'bans - 1298

The True Lifetime and a Possible Mechanism of the Nonelastic Scattering of the Current Carriers in Semiconductors. S. M. Ryvkin - 2148

Semiconductor Metallurgy

Certain Features of the Dependence of the Forbidden-Band Width and the Carrier Mobility on the Composition of Tellurium–Selenium and Tellurium–Sulfur Solid Solutions. V. N. Lange and A. R. Regel' - 2173

Crystal-Chemical Characteristics of Semiconducting Compounds of Transition Metals. L. D. Dudkin - 371

Effect of Thermal Treatment of Silicon on Minority Carrier Lifetime. V. A. Atsarkin and E. Z. Mazel' - 1874

Effect of Ultraviolet and X-Ray Radiation on the Internal Friction of Silver Chloride. M. P. Shaskol'skaya and Yu. Kh. Vekilov - 1001

Influence of the Concentration Dependence of the Coefficient of Segregation upon the Redistribution of Components in a Binary System with Directed Crystallization. V. N. Romanenko - 793

Method for Growing Uniform Monocrystals of Alloyed Semiconductor Materials, Solid Solutions, and Intermetallic Compounds of a Given Composition Determined by the Composition of the Melt. S. V. Airapetyants and G. I. Shmelev - 689

Nature of the Chemical Bonds and Electrical Conductivity of Compounds of the Structure Type of FeS_2. L. D. Dudkin and V. L. Vaidanich - 1384

Preparation of Homogeneous Solid Solutions in the AlSb–InSb System. B. V. Baranov and N. A. Goryunova - 262

Problem of the Interaction Between Copper and Antimony in Germanium. A. Ya. Potemkin and V. I. Potapov - 1668

Semiconducting Properties of the $AgFeTe_2$ Phase. E. L. Shtrum - 1352

Semiconducting Tin Dioxide. A. Ya. Kuznetsov - 30

Solid Solutions in Quaternary Systems Formed from InAs and InSb. N. A. Goryunova and V. D. Prochukhan - 161

The Effect of Tin Treatment on the Lifetime of Nonequilibrium Charge Carriers in Germanium. A. K. Mednikov - 215

Semiconductor Theory

A Remark Concerning Mooser and Pearson's Rule. E. L. Zorina - 1745

Concerning the Dependence of Phonon Spectrum on the Concentration of Free Charge Carriers. V. L. Bonch-Bruevich - 1678
Concerning the Properties of Germanium in a Strong Electric Field. G. M. Avak'yants - 744
Dependence of the Number of Radiation Defects in Silicon on the Initial Electron Energy. B. Ya. Yurkov - 2412
Determination of the Impurity Concentration in Germanium. R. M. Vinetskii and E. G. Miselyuk - 60
Injection Phenomenon During Flow of Current Through a Nonhomogeneous Semiconductor. Z. A. Demidenko and K. B. Tolypgo - 2452
Investigation of the Symmetry Properties of Energy Bands of Crystals of the SnSe and Sb_2S_3 Type. F. M. Gashimzade - 1856
Preparation and Properties of Glassy-Oxide Semiconductors of the $VO_{2.5}$–$PO_{2.5}$–RO_X Type. L. A. Grechanik, N. V. Petrovykh, and V. G. Karpechenko - 1908
Properties of Semiconductors with an Extremum Loop. I. Cyclotron and Combinational Resonance in a Magnetic Field Perpendicular to the Plane of the Loop. É. I. Rashba - 1109
Properties of Semiconductors with Extremal Loops. II. Magnetic Susceptibility in a Field Perpendicular to the Plane of the Loop. I. L. Boiko and É. I. Rashba - 1692
The Chemical Potential and the Criterion for Degeneracy of the Conductivity Electrons in a Strong Magnetic Field. A. I. Ansel'm and B. M. Askerov - 2512
The Problem of Internal Breakdown in Nonpolar Semiconductors. G. V. Gordeev - 571
Thermally Stimulated Conductivity in Semiconductors. I. I. Boiko, É. I. Rashba, and A. P. Trofimenko - 99
The Temperature Dependence of the Chemical Potential in a Semiconductor. S. I. Chanyshev and V. É. Zgaevskii - 2193
The True Lifetime and a Possible Mechanism of the Nonelastic Scattering of the Current Carriers in Semiconductors. S. M. Ryvkin - 2148

Spectra

Characteristic Temperature and Spectrum of Thermal Lattice Vibrations. A. P. Zvyagina and V. I. Iveronova - 108
Concerning the Dependence of Phonon Spectrum on the Concentration of Free Charge Carriers. V. L. Bonch-Bruevich - 1678
Determination of Recombination Constants from Spectral Characteristic of a Photoelement with a p-n Junction. V. K. Subashiev - 187
Energy Spectrum of Holes in Diamond-Type Crystals. K. Ya. Shtivel'man - 464
Energy Spectrum for Holes in Diamond-Type Crystals. K. Ya. Shtivel'man - 598
Fine Structure of the Fundamental Absorption Edge in Single Crystals of Cadmium Selenide. E. F. Gross and V. V. Sobolev - 379
Investigation of Plasmon Spectra. V. N. Ageev, L. A. Balabanova, and M. M. Bredov - 2578
Investigation of the Influence of Oriented Deformation upon the Spectrum of the Basic Absorption Edge of Single Cu_2O Crystals. E. F. Gross and A. A. Kaplyanskii - 2637
Investigation of the Photoconductivity-Response Spectrum of CdSe Monocrystals at 77 and 20° K. V. V. Eremenko - 2315
Investigation of the Photoconductivity-Response Spectrum of Mixed $CdS_X \cdot CdSe_{1-X}$ Monocrystals at 77 and 20° K. V. V. Eremenko - 2320
Polarization in the Absorption Spectrum of Cubic Cuprous Oxide. I. S. Gorban' and V. B. Timofeev - 1863
Quantum Efficiency of CdTe p-n Junctions in the Ultraviolet Part of the Spectrum. G. B. Dubrovskii - 536
Raman Scattering of Mixed Crystals of the Alkali Halide Salts. A. I. Stekhanov and M. B. Éliashberg - 2096
The Applicability of the Diffuse Reflection Spectrum Method for Determining the Forbidden Zone Width ΔE_{phot} in Powder Specimens. É. É. Godik and B. F. Ormont - 2680
The Structure of the Vibrational Spectrum of the Hydrogen Bond in Certain Crystals. A. I. Stekhanov and A. A. Klochikhin - 2605

Surface Properties

A Method for Experimentally Testing the Possibility of Employing a Universal Surface Recombination Velocity When Investigating the Kinetics of Photoelectric Processes. É. I. Rashba - 2397
Anisotropy of the Surface Breakdown of Germanium in Strong Fields. A. I. Morozov - 578
Approximate Calculation of the Surface Energy of Some Semiconductors Having the Structure of Diamond and of Zinc Blende. S. N. Zadumkin - 803
Determination of Carrier Mobility and Density in the Surface Layer of a Semiconductor. V. K. Subashchiev and S. A. Poltinnikov - 1059
Investigation of Surface Layers in Cadmium-Telluride Crystals. Yu. A. Vodakov, G. A. Lomakina, G. P. Naumov, and Yu. P. Maslakovets - 49
Investigation of the Kinetics of Fast Surface States in Germanium. V. G. Litovchenko and V. I. Lyashenko - 1442
Investigation of the Surface Electrical Conductivity of Single-Crystal Germanium. V. A. Presnov and V. F. Synorov - 357

Nature of Shear Formation on the Yield Surface of Metals. N. N. Davidenkov and É. I. Brainin - 1642
Nonequilibrium Carrier Lifetime in the Surface Layers of CdSe + Ag Monocrystals. U. B. Soltamov and I. G. Perestoronin - 21
Surface Properties of Silicon. V. G. Litovchenko and O. V. Snitko - 554
The Applicability of a Steady-State Photoconductivity Method of Investigation of the Dependence of Surface-Recombination Velocity on the Surface Potential. A. V. Rzhanov - 2166
The Energy Distribution of Surface Electron States for a Pure Germanium Surface With and Without the Presence of Adsorbed Oxygen. V. I. Lyaskenko, N. S. Chernaya, and A. B. Gerasimov - 2158
The Surface Conductivity of Cuprous Oxide Rectifiers. M. M. Kalabin and P. V. Sharavskii - 785

Thermal Properties and Effects

Application of Thermionic Emission from the Direct Conversion of Heat Energy to Electrical Energy. N. D. Morgulis and A. G. Naumovets - 501
Certain Properties of Thallium Selenide Monocrystals. G. A. Akhundov, G. B. Abdullaev, and G. D. Guseinov - 1378
Certain Properties of the CdSb–ZnSb System. I. M. Pilat, G. S. Borodinets, L. A. Kosyachenko, and V. I. Malko - 1381
Changes of the Dielectric Properties of Rutile Ceramics During the Passage of Current and During Heating. V. Ya. Kunin and A.N. Chikik - 2101
Characteristic Temperature and Spectrum of Thermal Lattice Vibrations. A. P. Zvyagina and V. I. Iveronova - 108
Concerning the Efficiency of Thermobattery Cooling. A. I. Burshtein - 2236
Effect of a Magnetic Field on the Heat Conduction of Indium Antimonide. D. Kh. Amirkhanova and R. I. Bashirov - 1447
Effect of the Anisotropy of Crystals on the Thermal Vibration of Atoms in Ge and Si. A. G. Samoilovich and V. D. Iskra - 2517
Experimental Investigation of Two Kelvin Equations. I. K. Kristensen - 2356
Fused Quartz as a Model Material in Thermal Conductivity Measurements. E. D. Devyatkova, A. V. Petrov, I. A. Smirnov, and B. Ya. Moizhes - 681
Heat Capacity of the Trisulfides of Arsenic, Antimony, and Bismuth in Connection with Their Structural and Physical-Chemical Properties. V. A. Romanovskii and V. V. Tarasov - 1170
Injection Heat Transfer. V. I. Stafeev - 406
Irreversible Thermal Changes of Shape in Cadmium-Lead and Cadmium-Zinc Alloys. N. N. Davidenkov, V. A. Likhachev, and G. A. Malygin - 2183
Low-Temperature Heat Capacity and Entropy at 298.1°K of the Sulfides of Elements in Group V of The D. I. Mendeleev Periodic Table. V. A. Romanovskii and V. V. Tarasov - 1176
On the Thermal Dissociation Energy of F-Centers in KCl. L. M. Shamovskii, A. A. Dunina, and M. I. Gosteva - 2252
Photodielectric Properties of Polycrystalline Cadmium Selenide. I. High Temperatures. Ya. A. Oksman and A. V. Burlakov - 1700
Properties of Thermally Induced Conductivity in Single Crystals of CdS. A. P. Trofimenko, G. A. Fedorus, and A. K. Razmadze - 1033
Study of the Thermal Expansion of α-Sn, InSb, and CdTe. S. I. Novikova - 2087
Temperature Dependence of ε' and ε'' of Strontium-Bismuth Titanate and of Barium Titanate at Frequencies of 9400 Mc. G. L. Lipaeva and G. I. Skanavi - 472
The Change in the Microstructure of Uranium on Cyclic Heat Treatment. R. I. Garber, S. Ya. Zalivadnyi, and V. M. Mikhailovskii - 950
Theory of Heat Conductivity of Ferrodielectric Materials at Low Temperatures. A. I. Akhiezer and V. G. Bar'yakhtar - 2178
Theory of Orientation Ordering of Dipole Crystals. V. I. Klyachkin - 1263
Theory of the Phonon Thermal Conductivity of a Nonideal Crystal Near a Critical Point on a Curve of Dissociation or of Phase Transition of the Second Kind. M. A. Krivoglaz - 1087
The Relationship Between Thermal and Optical Properties of In_2Te_3. V. A. Petrusevich, V. M. Sergeeva, and I. A. Smirnov - 2573
Thermal Conductivity of α- and β-Modifications of In_2Te_3. A. I. Zaslavskii, V. M. Sergeeva, and I. A. Smirnov - 2565
Thermal Conductivity of p- and n-Type Germanium with Different Concentrations in the Temperature Range 80 to 440°K. E. D. Devyatkova and I. A. Smirnov - 527
Thermal Conductivity of Semiconductor Solid Solutions. A. V. Ioffe and A. F. Ioffe - 719
Thermal Effects in the Study of the Electrical Conductivity of Germanium in Liquid Helium. É. L. Zavaritskaya - 2873
Thermal Expansion of Diamonds Between 25 and 750°K. S. I. Novikova - 1464
Thermal Expansion of Germanium at Low Temperatures. S. I. Novikova - 37
Thermomagnetic Phenomena in Semimetals in a Strong Magnetic Field. A. I. Ansel'm and B. M. Askerov - 2060

Thermomagnetic Properties of Gallium Antimonide. D. Kh. Amirkhanova - 1019
The Temperature Dependence of the Chemical Potential in a Semiconductor. S. L. Chanyshev and V. É. Zgaevskii - 2193
The Thermal Conductivity and the Dependence of the Lorentz Number in PbSe on Temperature and on the Degree of the Electron-Gas Degeneracy. E. D. Devyatkova and I. A. Smirnov - 1786
Use of the Theory of Damping in Calculations of Kinetic Coefficients. M. I. Klinger - 2747
Various Steady-State Methods for Measuring the Thermal Conductivity of Semiconductors. A. F. Chudnovskii - 2810

Thermoelectric Properties and Effects
An Investigation of the Semiconducting Properties in the Silicon–Cobalt System. E. N. Nikitin - 588
Bridgman Effect in Bismuth Telluride Crystals. P. I. Baranskii and S. L. Tomkevich - 1551
Concerning a Rapid Method of Precise Measurements of Thermal emf of Semiconductors. O. V. Emel'yanenko and F. P. Kesamanly - 1356
Concerning the Regeneration Circuit of Thermoelectric Cooling. A. I. Burshtein - 1456
Dependence of the Volume Peltier Effect on Resistivity Gradients. P. I. Baranskii and P. M. Kurilo - 424
Inversion of Thermoelectric Power in the Region of Welded Contacts Between Metals. L. N. Érastov - 254
On Power Application of Thermoelectric Elements. A. F. Ioffe, B. Ya. Moizhes, and L. S. Stil'bans - 2524
Temperature Dependence of Basic Parameters of GaAs Point-Contact Diodes. D. N. Nasledov, N. N. Smirnova, and B. V. Tsarenkov - 2460
The Effective Carrier Mass in Lead Selenide. I. A. Smirnov, B. Ya. Moizhes, and E. D. Nensberg - 1793
The Influence of Omnidirectional Pressure Upon the Electrical Conductivity and Thermal Electromotive Force of In_2Te_3. A. A. Averkin, V. M. Sergeeva, and A. I. Shelykh - 319
The Influence of the Temperature Dependence of Physical Parameters on the Efficiency of Thermoelectric Generators and Refrigerators. B. Ya. Moizhes - 671
Thermal Electron Emission from Barium Tungstate. A. I. Mel'nikov, A. V. Morosov, R. B. Sobolevskaya, and A. R. Shul'man - 650
Thermoelectric Properties of a Gaseous Semiconductor. V. G. Yur'ev - 2602
Thermoelectric Properties of Alloys of the Pseudobinary System Sb_2Te_3–Bi_2Te_3. G. V. Kokosh and S. S. Sinani - 1012
Thermoelectric Properties of Solid Solutions of Chromium, Vanadium, and Titanium in Nickel. M. V. Vedernikov and N. V. Kolomoets - 2420
Thermoelectric Properties of the Intermetallic Compound $MnAl_3$. N. V. Kolomoets and E. A. Popova - 1758
Thermoelectric Properties of the Silicon–Chromium System. E. N. Nikitin - 2389
The Thermal Conductivity and the Dependence of the Lorentz Number in PbSe on Temperature and on the Degree of the Electron-Gas Degeneracy. E. D. Devyatkova and I. A. Smirnov - 1786
The Volume-Gradient Thomson Effect. P. I. Baranskii - 413

Vacuum Techniques
Variation of the Time Necessary to Rupture Solids in High Vacuum as a Function of Stress. S. N. Zhurkov, B. Ya. Levin, and É. E. Tomashevskii - 1853

X-Rays
Investigation of the Submicroporosity of Low-Absorption Materials by the Method of Multiple Small-Angle Scattering of X-Rays. G. M. Plavnik and B. M. Rovinskii - 994
On the Influence of Illumination upon the Intensity of X-Ray Reflections from a Cadmium Sulfide Crystal. M. A. Rumsh, Yu. N. Shuvalov, and L. A. Smirnov - 341
Study of the Decomposition of a Supersaturated Solid Solution of Copper in Germanium. A. M. Elistratov and P. R. Kamadzhiev - 2621
The Effect of X-Ray Irradiation on the Anomalous Properties of Rochelle Salt. K. N. Karmen - 629
X-Ray Investigation of the Phase Composition of Ni-Zn-Ferrites with the CoK_α Radiation. V. V. Latsh, N. G. Minaev, and B. Kh. Somin - 1479
X-Ray Investigation of the Tellurium-Selenium System. T. P. Smorodina - 807

Zone Melting
Purification of Tellurium by the Zone Melting Method. N. F. Shvartsenau - 797
The Distribution Coefficient of Tin in Selenium. D. M. Chizhikov and V. M. Édel'shtein - 790